

# TPS255xx 高精度、可変電流制限の電力分配スイッチ

## 1 特長

- 1.5Aまでの最大負荷電流
- 1.7Aにおいて $\pm 6\%$ の電流制限精度(標準値)
- USBの電流制限要件に適合
- TPS2550およびTPS2551と下位互換
- 電力制限の可変範囲: 75mA～1700mA (標準値)
- 定電流(TPS255x)およびラッチ・オフ(TPS255x-1)バージョン
- 過電流への高速な応答 - 2 $\mu$ s (標準値)
- 85m $\Omega$ のハイサイドMOSFET (DBVパッケージ)
- 逆入出力電圧に対する保護
- 動作範囲: 2.5V～6.5V
- ソフトスタート機能内蔵
- IEC 61000-4-2に従い15kVのESD保護(外部容量あり)
- UL認定済み- ファイルNo. E169910およびNEMKO IEC60950-1-am1 ed2.0
- TIスイッチ・ポートフォリオを参照

## 2 アプリケーション

- USBポートおよびハブ
- デジタルTV
- セットトップ・ボックス
- VOIP電話

## 3 概要

TPS255xおよびTPS255x-1電力分配スイッチは、正確な電流制限が必要な、または大きな容量性負荷があり短絡が発生するようなアプリケーションを対象としており、1.5Aまでの連続的な負荷電流を供給できます。これらのデバイスは、外付け抵抗により電流制限スレッショルドを75mA～1.7Aまで(標準値)の範囲でプログラム可能です。電流制限の精度は、より高い電流制限設定において、 $\pm 6\%$ まで高めることができます。この電源スイッチの立ち上がりおよび立ち下がり時間は、オン/オフ時の電流サージを最小限に抑えるように制御されます。

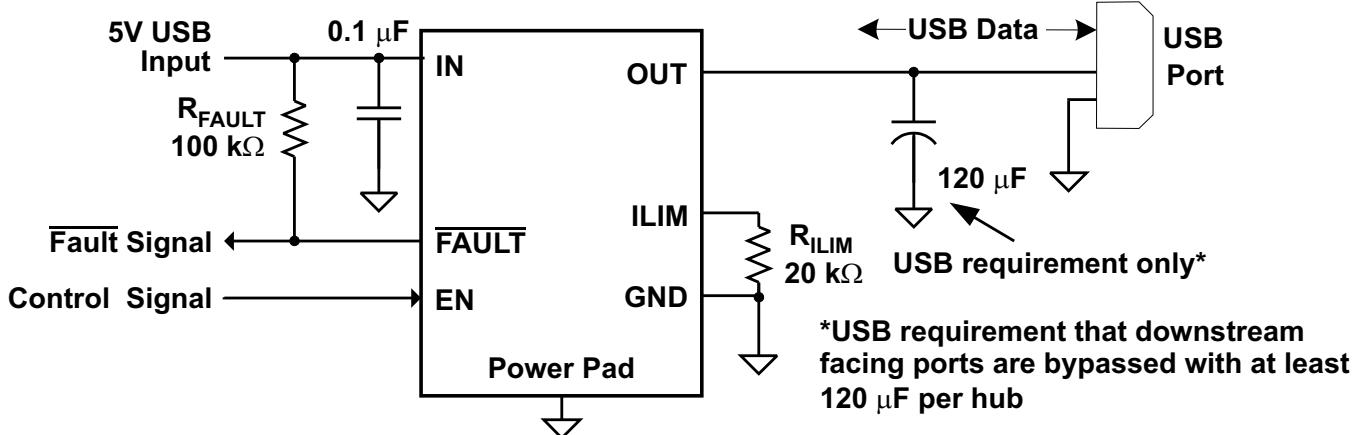
TPS255xデバイスは、出力負荷が電流制限スレッショルドを超過したときに、定電流モードを使用して、出力電流を安全なレベルに制限します。TPS255x-1デバイスは、過電流または逆電圧の状況で電力スイッチをラッチオフし、回路ブレーカー機能を提供します。内蔵の逆電圧コンバーラータは、出力電圧が入力よりも高く駆動されたときに電力スイッチをディセーブルし、スイッチの入力側にあるデバイスを保護します。過電流および逆電圧状態の間、FAULT出力がLOWにアサートされます。

### 製品情報<sup>(1)</sup>

| 型番      | パッケージ      | 本体サイズ(公称)     |
|---------|------------|---------------|
| TPS2552 | SOT-23 (6) | 2.90mm×1.60mm |
|         | WSON (6)   | 2.00mm×2.00mm |
| TPS2553 | SOT-23 (6) | 2.90mm×1.60mm |
|         | WSON (6)   | 2.00mm×2.00mm |

(1) 提供されているすべてのパッケージについては、巻末の注文情報をお参照ください。

### 代表的なアプリケーション TPS2552/53



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English Data Sheet: [SLVS841](http://www.ti.com)

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## 4 改訂履歴

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

| Revision E (February 2012) から Revision F に変更   | Page     |
|--|----------|
| • 「ESD定格」表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクション 追加 ..... | <b>1</b> |
| • 「特長」の下の箇条書きで、電流制限の可変範囲を1300mAから1700mAへ 変更 .....  | <b>1</b> |
| • Changed from 1.2 A to 1.5 A .....  | <b>4</b> |

| Revision D (June 2011) から Revision E に変更                                       | Page     |
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| • 変更 $V_{EN}$ to $V_{\overline{EN}}$ in Recommended Operating Conditions ..... | <b>6</b> |
| • 変更 $V_{\overline{EN}}$ to $V_{EN}$ in Recommended Operating Conditions ..... | <b>6</b> |

| Revision C (September 2009) から Revision D に変更  | Page      |
|--|-----------|
| • 「特長」の「過電流への高速な応答 - $2\mu S$ (標準値)」を「過電流への高速な応答 - $2\mu S$ (標準値)」へ 変更 .....                 | <b>1</b>  |
| • 「特長」に「UL認定済み」および「NEMCO IEC60950-1-am1 ed2.0」のテキストを追加 .....                                 | <b>1</b>  |
| • 「特長」に「TIスイッチ・ポートフォリオを参照」の項目を追加 .....   | <b>1</b>  |
| • 注記3を削除、「製品情報」表を 変更 .....   | <b>1</b>  |
| • 追加 ESD-system level (contact/air) to the ABS MAX table, and Added Note 3 .....             | <b>6</b>  |
| • 追加 text to the REVERSE-VOLTAGE PROTECTION section: "A reverse.....when this occurs." ..... | <b>14</b> |

**Revision B (February 2009) から Revision C に変更**
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| • 1.3A (標準値)から1.7A (標準値)へ 変更 .....  | 1  |
| • テキスト「1.5Aまでの連続的な負荷電流を供給」を追加.....  | 1  |
| • Changed From: $19.1\text{ k}\Omega \leq R_{ILIM} \leq 232\text{ k}\Omega$ To: $15\text{ k}\Omega \leq R_{ILIM} \leq 232\text{ k}\Omega$ .....   | 5  |
| • 変更 $I_{OUT}$ values for 1.2A and 1.5A.....  | 6  |
| • 変更 $T_J$ values for 1.2A and 1.5A .....   | 6  |
| • 追加 $R_{ILIM} = 15\text{ k}\Omega$ option.....   | 7  |
| • 変更 Text From: current-limit threshold between 75 mA and 1.3 A (typ) To: current-limit threshold between 75 mA and 1.7 A (typ) .....   | 13 |
| • 変更 Text From: The recommended 1% resistor range for $R_{ILIM}$ is $19.1\text{ k}\Omega \leq R_{ILIM} \leq 232\text{ k}\Omega$ to ensure stability To: The recommended 1% resistor range for $R_{ILIM}$ is $15\text{ k}\Omega \leq R_{ILIM} \leq 232\text{ k}\Omega$ to ensure stability ..... | 15 |
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| • 変更 図 17 Title From: Current Limit Threshold Vs $R_{ILIM}$ ..... | 9 |
| • 変更 図 18 Title From: Current Limit Threshold Vs $R_{ILIM}$ ..... | 9 |

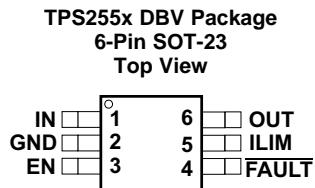
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## 5 Device Comparison Table

| GENERAL SWITCH CATALOG  |  |  |   |   |  |   |
|---|--|--|---|---|--|---|
| 33 mΩ, single   | 80 mΩ, single  | 80 mΩ, dual  | 80 mΩ, dual   | 80 mΩ, triple   | 80 mΩ, quad  | 80 mΩ, quad   |
| <br>TPS201xA 0.2 A - 2 A<br>TPS202x 0.2 A - 2 A<br>TPS203x 0.2 A - 2 A | <br>TPS2014 600 mA<br>TPS2015 1 A<br>TPS2041B 500 mA<br>TPS2051B 500 mA<br>TPS2045A 250 mA<br>TPS2049 100 mA<br>TPS2055A 250 mA<br>TPS2061 1 A<br>TPS2065 1 A<br>TPS2068 1.5 A<br>TPS2069 1.5 A | <br>TPS2042B 500 mA<br>TPS2052B 500 mA<br>TPS2046B 250 mA<br>TPS2056 250 mA | <br>TPS2080 500 mA<br>TPS2081 500 mA<br>TPS2082 500 mA<br>TPS2062 1 A<br>TPS2090 250 mA<br>TPS2066 1 A<br>TPS2060 1.5 A<br>TPS2064 1.5 A | <br>TPS2043B 500 mA<br>TPS2053B 500 mA<br>TPS2057A 250 mA<br>TPS2063 1 A<br>TPS2067 1 A | <br>TPS2044B 500 mA<br>TPS2054B 500 mA<br>TPS2048A 250 mA<br>TPS2058 250 mA | <br>TPS2085 500 mA<br>TPS2086 500 mA<br>TPS2087 500 mA<br>TPS2095 250 mA<br>TPS2096 250 mA<br>TPS2097 250 mA |

## 6 Pin Configuration and Functions



EN = Active Low for the TPS2552

EN = Active High for the TPS2553

Add –1 to part number for latch-off version



EN = Active Low for the TPS2552

EN = Active High for the TPS2553

Add –1 to part number for latch-off version

### Pin Functions

| NAME      | PIN     |      |         |      | I/O | DESCRIPTION  |  |  |
|-----------|---------|------|---------|------|-----|--|--|--|
|           | TPS2552 |      | TPS2553 |      |     |  |  |  |
|           | SOT-23  | WSON | SOT-23  | WSON |     |  |  |  |
| EN        | 3       | 4    | —       | —    | I   | Enable input, logic low turns on power switch  |  |  |
| EN        | —       | —    | 3       | 4    | I   | Enable input, logic high turns on power switch   |  |  |
| FAULT     | 4       | 3    | 4       | 3    | O   | Active-low open-drain output, asserted during overcurrent, overtemperature, or reverse-voltage conditions.                     |  |  |
| GND       | 2       | 5    | 2       | 5    | —   | Ground connection; connect externally to PowerPAD  |  |  |
| ILIM      | 5       | 2    | 5       | 2    | O   | External resistor used to set current-limit threshold; recommended $15\text{ k}\Omega \leq R_{ILIM} \leq 232\text{ k}\Omega$ . |  |  |
| IN        | 1       | 6    | 1       | 6    | I   | Input voltage; connect a $0.1\text{ }\mu\text{F}$ or greater ceramic capacitor from IN to GND as close to the IC as possible.  |  |  |
| OUT       | 6       | 1    | 6       | 1    | O   | Power-switch output  |  |  |
| PowerPAD™ | —       | PAD  | —       | PAD  | —   | Internally connected to GND; used to heat-sink the part to the circuit board traces. Connect PowerPAD to GND pin externally.   |  |  |

Add –1 for Latch-Off version

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)(2)</sup>

|   | MIN   | MAX | UNIT |
|---|---|-----|------|
| Voltage range on IN, OUT, EN or $\overline{EN}$ , ILIM, FAULT | -0.3  | 7   | V    |
| Voltage range from IN to OUT                                  | -7  | 7   | V    |
| $I_O$ Continuous output current                               | Internally Limited                          |     |      |
| Continuous total power dissipation                            | See the <a href="#">Thermal Information</a> |     |      |
| Continuous FAULT sink current                                 | 0   | 25  | mA   |
| ILIM source current   | 0   | 1   | mA   |
| $T_J$ Maximum junction temperature                            | -40   | 150 | °C   |
| $T_{stg}$ Storage temperature                                 | -65   | 150 | °C   |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Voltages are referenced to GND unless otherwise noted.

## 7.2 ESD Ratings

|                    |                         | VALUE  | UNIT   |
|--------------------|-------------------------|--|--------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000  |
|                    |                         | Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±500   |
|                    |                         | IEC 61000-4-2 contact discharge <sup>(3)</sup>                                 | ±8000  |
|                    |                         | IEC 61000-4-2 air-gap discharge <sup>(3)</sup>                                 | ±15000 |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

(3) Surges per EN61000-4-2. 1999 applied to output terminals of EVM. These are passing test levels, not failure threshold.

## 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                   |  | MIN                              | NOM | MAX  | UNIT |
|-------------------|--|----------------------------------|-----|------|------|
| V <sub>IN</sub>   | Input voltage, IN  | 2.5                              | 6.5 |      | V    |
| V <sub>EN</sub>   | Enable voltage   | TPS2552/52-1                     | 0   | 6.5  | V    |
| V <sub>EN</sub>   | Enable voltage   | TPS2553/53-1                     | 0   | 6.5  | V    |
| V <sub>IH</sub>   | High-level input voltage on EN or $\overline{EN}$                    |                                  | 1.1 |      |      |
| V <sub>IL</sub>   | Low-level input voltage on EN or $\overline{EN}$                     |                                  |     | 0.66 | V    |
| I <sub>OUT</sub>  | Continuous output current,<br>OUT                                    | −40 °C ≤ T <sub>J</sub> ≤ 125 °C | 0   | 1.2  | A    |
|                   |  | −40 °C ≤ T <sub>J</sub> ≤ 105 °C | 0   | 1.5  |      |
| R <sub>ILIM</sub> | Current-limit threshold resistor range (nominal 1%) from ILIM to GND | 15                               | 232 |      | kΩ   |
| I <sub>O</sub>    | Continuous $\overline{FAULT}$ sink current                           | 0                                | 10  |      | mA   |
|                   | Input de-coupling capacitance, IN to GND                             | 0.1                              |     |      | μF   |
| T <sub>J</sub>    | Operating virtual junction<br>temperature <sup>(1)</sup>             | I <sub>OUT</sub> ≤ 1.2 A         | −40 | 125  | °C   |
|                   |  | I <sub>OUT</sub> ≤ 1.5 A         | −40 | 105  |      |

(1) See [Power Dissipation and Junction Temperature](#) for details on how to calculate maximum junction temperature for specific applications and packages.

## 7.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup>        | TPS2552                                      |            | TPS2553      |            | UNIT |      |
|--------------------------------------|--|------------|--------------|------------|------|------|
|                                      | DBV (SOT-23)                                 | DRV (WSON) | DBV (SOT-23) | DRV (WSON) |      |      |
|                                      | 6 PINS                                       | 6 PINS     | 6 PINS       | 6 PINS     |      |      |
| R <sub>θJA</sub>                     | Junction-to-ambient thermal resistance       | 182.6      | 72           | 182.6      | 72   | °C/W |
| R <sub>θJC(to</sub><br><sub>p)</sub> | Junction-to-case (top) thermal resistance    | 122.2      | 85.3         | 122.2      | 85.3 | °C/W |
| R <sub>θJB</sub>                     | Junction-to-board thermal resistance         | 29.4       | 41.3         | 29.4       | 41.3 | °C/W |
| Ψ <sub>JT</sub>                      | Junction-to-top characterization parameter   | 20.8       | 1.7          | 20.8       | 1.7  | °C/W |
| Ψ <sub>JB</sub>                      | Junction-to-board characterization parameter | 28.9       | 41.7         | 28.9       | 41.7 | °C/W |
| R <sub>θJC(b</sub><br><sub>ot)</sub> | Junction-to-case (bottom) thermal resistance | —          | 11.1         | —          | 11.1 | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

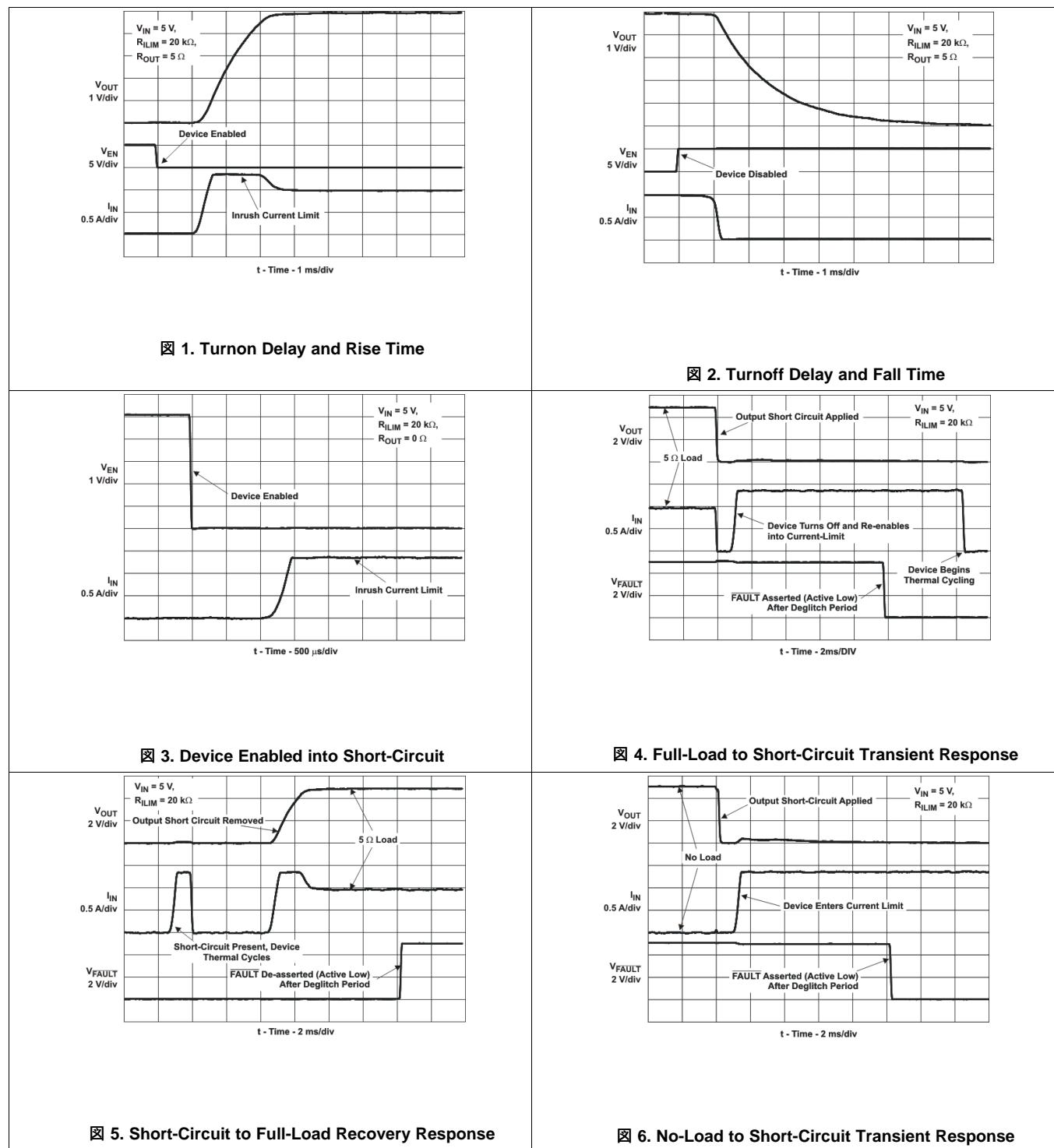
## 7.5 Electrical Characteristics

over recommended operating conditions,  $V_{EN} = 0$  V, or  $V_{EN} = V_{IN}$ ,  $R_{FAULT} = 10$  k $\Omega$  (unless otherwise noted)

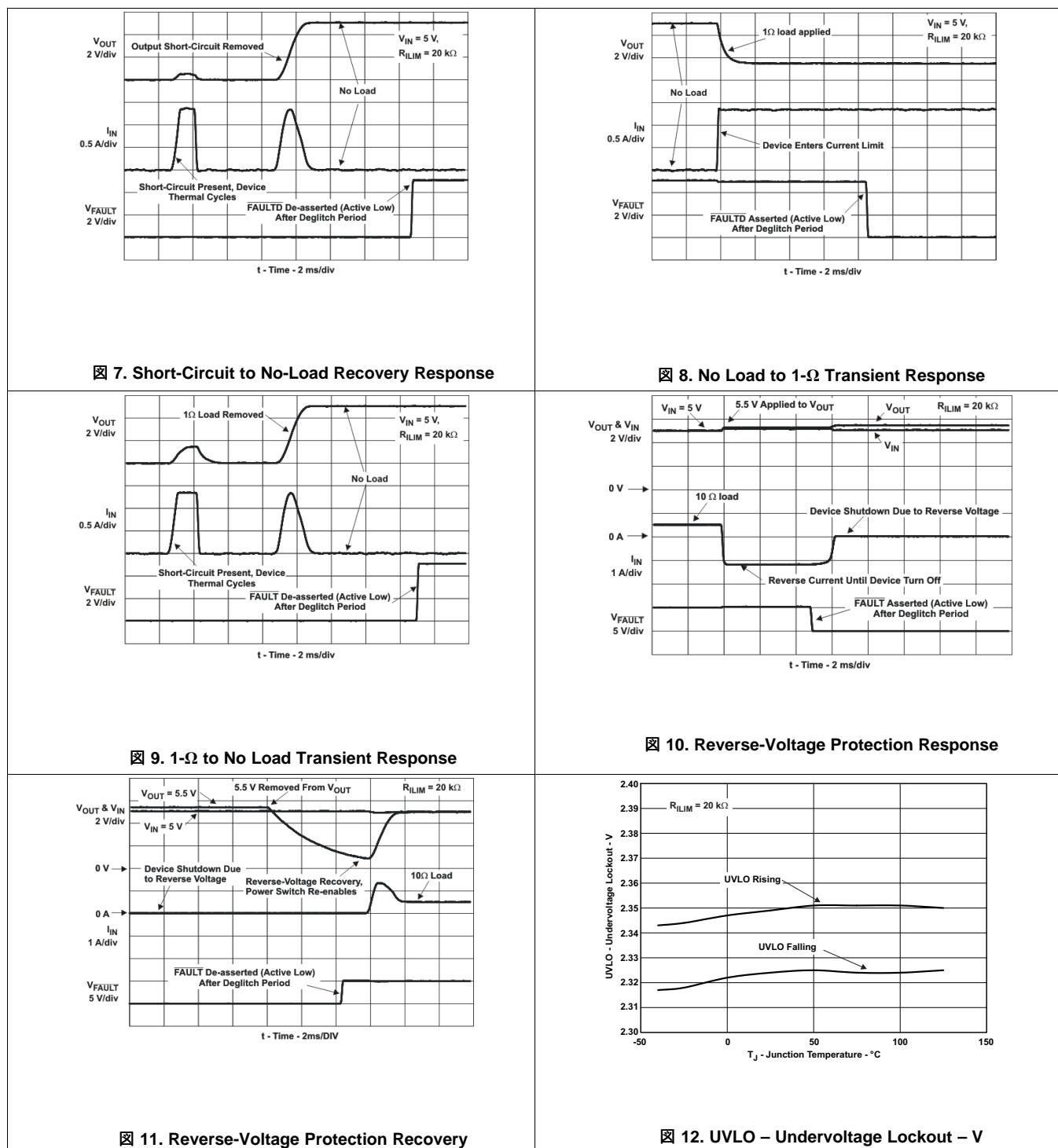
| PARAMETER  | TEST CONDITIONS <sup>(1)</sup>   | MIN   | TYP  | MAX  | UNIT          |    |
|--|--|---|------|------|---------------|----|
| <b>POWER SWITCH</b>  |  |   |      |      |               |    |
| $r_{DS(on)}$ Static drain-source on-state resistance   | DBV package, $T_J = 25^\circ\text{C}$  | 85  | 95   |      | m $\Omega$    |    |
|  | DBV package, $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$                 |   | 135  |      |               |    |
|  | DRV package, $T_J = 25^\circ\text{C}$  | 100   | 115  |      |               |    |
|  | DRV package, $-40^\circ\text{C} \leq T_J \leq 105^\circ\text{C}$                 |   | 140  |      |               |    |
|  | DRV package, $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$                 |   | 150  |      |               |    |
| $t_r$ Rise time, output  | $C_L = 1$ $\mu\text{F}$ , $R_L = 100$ $\Omega$ ,<br>(see <a href="#">图 20</a> )  | $V_{IN} = 6.5$ V                                    | 1.1  | 1.5  | ms            |    |
|  |  | $V_{IN} = 2.5$ V                                    | 0.7  | 1    |               |    |
| $t_f$ Fall time, output  | $C_L = 1$ $\mu\text{F}$ , $R_L = 100$ $\Omega$ ,<br>(see <a href="#">图 20</a> )  | $V_{IN} = 6.5$ V                                    | 0.2  | 0.5  |               |    |
|  |  | $V_{IN} = 2.5$ V                                    | 0.2  | 0.5  |               |    |
| <b>ENABLE INPUT EN OR <math>\overline{EN}</math></b>   |  |   |      |      |               |    |
| Enable pin turn on/off threshold   |  | 0.66  | 1.1  |      | V             |    |
| $I_{EN}$ Input current   | $V_{EN} = 0$ V or 6.5 V, $V_{EN} = 0$ V or 6.5 V                                 | -0.5  | 0.5  |      | $\mu\text{A}$ |    |
| $t_{on}$ Turnon time   | $C_L = 1$ $\mu\text{F}$ , $R_L = 100$ $\Omega$ , (see <a href="#">图 20</a> )     |   | 3    |      | ms            |    |
| $t_{off}$ Turnoff time   | $C_L = 1$ $\mu\text{F}$ , $R_L = 100$ $\Omega$ , (see <a href="#">图 20</a> )     |   | 3    |      | ms            |    |
| <b>CURRENT LIMIT</b>   |  |   |      |      |               |    |
| $I_{OS}$ Current-limit threshold (Maximum DC output current $I_{OUT}$ delivered to load) and Short-circuit current, OUT connected to GND | $R_{ILIM} = 15$ k $\Omega$ , $-40^\circ\text{C} \leq T_J \leq 105^\circ\text{C}$ | 1610  | 1700 | 1800 | mA            |    |
|  | $R_{ILIM} = 20$ k $\Omega$   | $T_J = 25^\circ\text{C}$                            | 1215 | 1295 | 1375          |    |
|  |  | $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$ | 1200 | 1295 | 1375          |    |
|  | $R_{ILIM} = 49.9$ k $\Omega$   | $T_J = 25^\circ\text{C}$                            | 490  | 520  | 550           |    |
|  |  | $-40^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$ | 475  | 520  | 565           |    |
|  | $R_{ILIM} = 210$ k $\Omega$  |   | 110  | 130  | 150           |    |
| $t_{OS}$ Response time to short circuit  | $V_{IN} = 5$ V (see <a href="#">图 21</a> )                                       |   | 50   | 75   | 100           | μs |
| <b>REVERSE-VOLTAGE PROTECTION</b>  |  |   |      |      |               |    |
| Reverse-voltage comparator trip point ( $V_{OUT} - V_{IN}$ )   |  | 95  | 135  | 190  | mV            |    |
| Time from reverse-voltage condition to MOSFET turn off   | $V_{IN} = 5$ V   | 3   | 5    | 7    | ms            |    |
| <b>SUPPLY CURRENT</b>  |  |   |      |      |               |    |
| $I_{IN\_off}$ Supply current, low-level output   | $V_{IN} = 6.5$ V, No load on OUT, $V_{EN} = 6.5$ V or $V_{EN} = 0$ V             | 0.1   | 1    |      | $\mu\text{A}$ |    |
| $I_{IN\_on}$ Supply current, high-level output   | $V_{IN} = 6.5$ V, No load on OUT   | $R_{ILIM} = 20$ k $\Omega$                          | 120  | 140  | $\mu\text{A}$ |    |
|  |  | $R_{ILIM} = 210$ k $\Omega$                         | 100  | 120  | $\mu\text{A}$ |    |
| $I_{REV}$ Reverse leakage current  | $V_{OUT} = 6.5$ V, $V_{IN} = 0$ V  | $T_J = 25^\circ\text{C}$                            | 0.01 | 1    | $\mu\text{A}$ |    |
| <b>UNDERVOLTAGE LOCKOUT</b>  |  |   |      |      |               |    |
| UVLO Low-level input voltage, IN   | $V_{IN}$ rising  | 2.35  | 2.45 |      | V             |    |
| Hysteresis, IN   | $T_J = 25^\circ\text{C}$   |   | 25   |      | mV            |    |
| <b>FAULT FLAG</b>  |  |   |      |      |               |    |
| $V_{OL}$ Output low voltage, $\overline{FAULT}$  | $I_{FAULT} = 1$ mA   |   | 180  |      | mV            |    |
| Off-state leakage  | $V_{FAULT} = 6.5$ V  |   | 1    |      | $\mu\text{A}$ |    |
| $\overline{FAULT}$ deglitch  | $\overline{FAULT}$ assertion or de-assertion due to overcurrent condition        |   | 5    | 7.5  | 10            | ms |
|  | $\overline{FAULT}$ assertion or de-assertion due to reverse-voltage condition    |   | 2    | 4    | 6             | ms |
| <b>THERMAL SHUTDOWN</b>  |  |   |      |      |               |    |
| Thermal shutdown threshold   |  | 155   |      |      | °C            |    |
| Thermal shutdown threshold in current-limit  |  | 135   |      |      | °C            |    |
| Hysteresis   |  | 10  |      |      | °C            |    |

(1) Pulse-testing techniques maintain junction temperature close to ambient temperature; thermal effects must be taken into account separately.

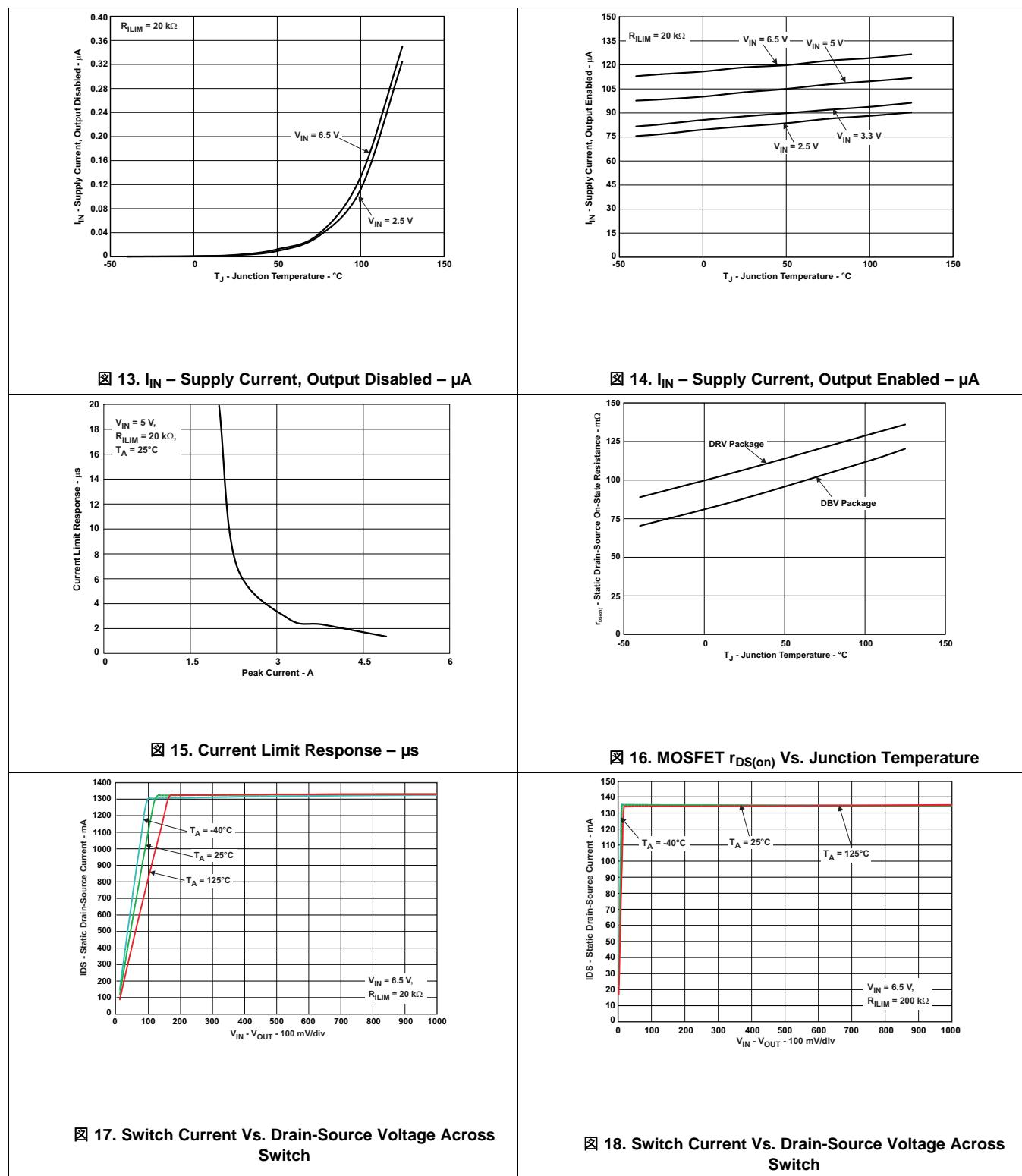
## 7.6 Typical Characteristics



## Typical Characteristics (continued)



## Typical Characteristics (continued)



## 8 Parameter Measurement Information

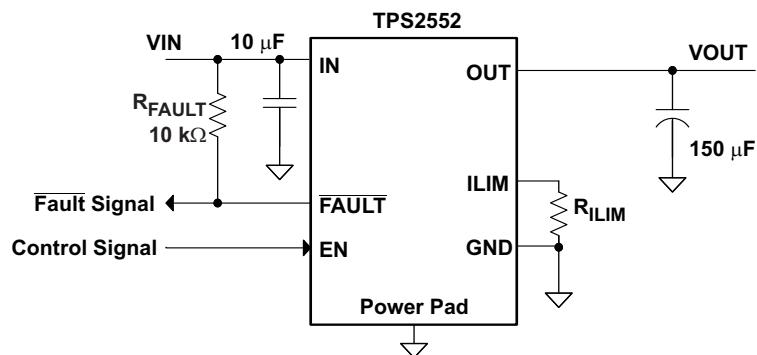


図 19. Typical Characteristics Reference Schematic

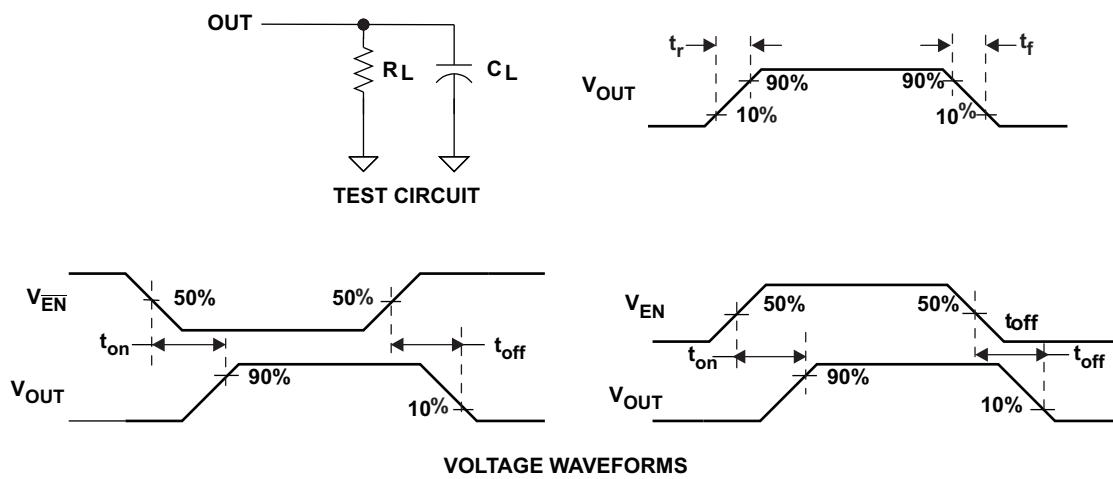


図 20. Test Circuit and Voltage Waveforms

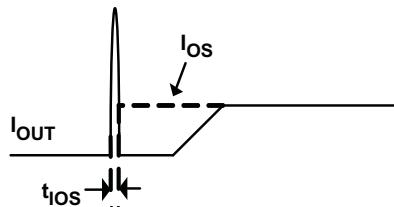


図 21. Response Time to Short-Circuit Waveform

### Parameter Measurement Information (continued)

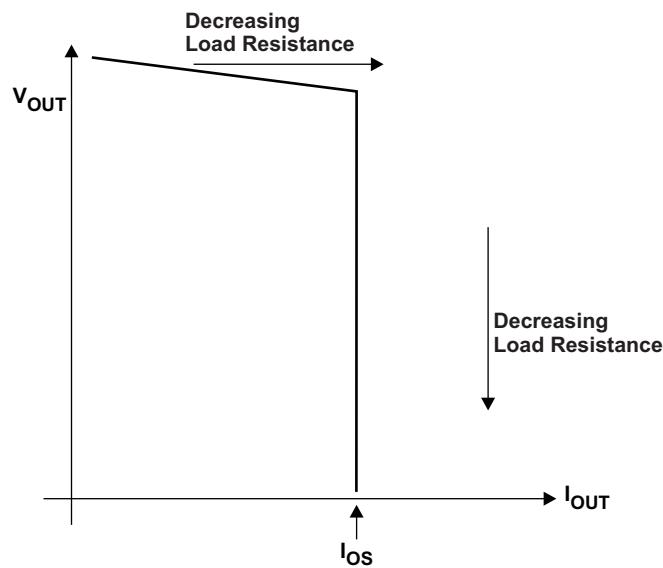


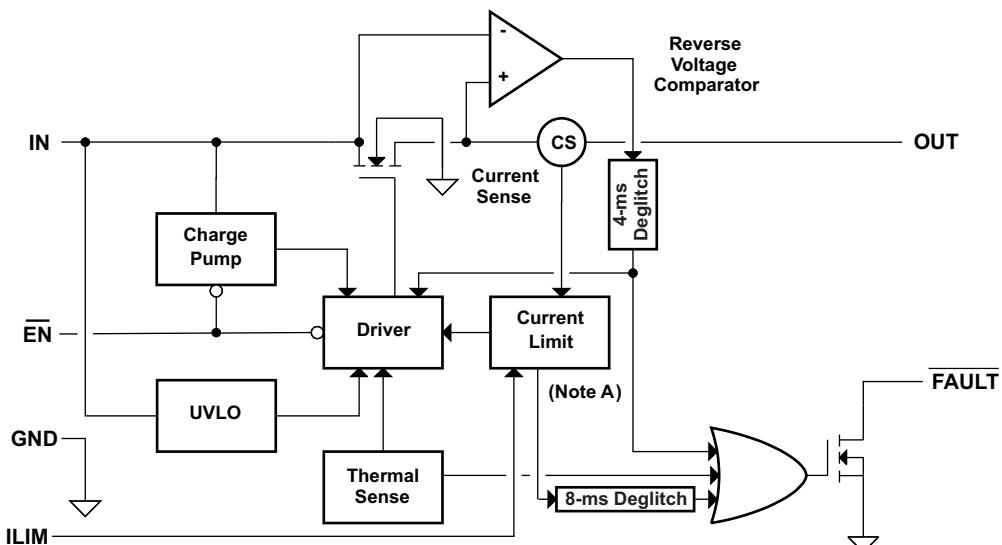
図 22. Output Voltage vs Current-Limit Threshold

## 9 Detailed Description

### 9.1 Overview

The TPS255x and TPS255x-1 are current-limited, power-distribution switches using N-channel MOSFETs for applications where short circuits or heavy capacitive loads are encountered and provide up to 1.5 A of continuous load current. These devices allow the user to program the current-limit threshold between 75 mA and 1.7 A (typical) through an external resistor. Additional device shutdown features include overtemperature protection and reverse-voltage protection. The device incorporates an internal charge pump and gate drive circuitry necessary to drive the N-channel MOSFET. The charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source. The charge pump operates from input voltages as low as 2.5 V and requires little supply current. The driver controls the gate voltage of the power switch. The driver incorporates circuitry that controls the rise and fall times of the output voltage to limit large current and voltage surges and provides built-in soft-start functionality. There are two device families that handle overcurrent situations differently. The TPS255x family enters constant-current mode while the TPS255x-1 family latches off when the load exceeds the current-limit threshold.

### 9.2 Functional Block Diagram



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A. TPS255x parts enter constant current mode during current limit condition; TPS255x-1 parts latch off

## 9.3 Feature Description

### 9.3.1 Overcurrent Conditions

The TPS255x and TPS255x-1 respond to overcurrent conditions by limiting their output current to the  $I_{OS}$  levels shown in [图 23](#). When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Two possible overload conditions can occur.

The first condition is when a short circuit or partial short circuit is present when the device is powered-up or enabled. The output voltage is held near zero potential with respect to ground and the TPS255x ramps the output current to  $I_{OS}$ . The TPS255x devices limits the current to  $I_{OS}$  until the overload condition is removed or the device begins to thermal cycle. The TPS255x-1 devices will limit the current to  $I_{OS}$  until the overload condition is removed or the internal deglitch time (7.5-ms typical) is reached and the device is turned off. The device remains off until power is cycled or the device enable is toggled.

## Feature Description (continued)

The second condition is when a short circuit, partial short circuit, or transient overload occurs while the device is enabled and powered on. The device responds to the overcurrent condition within time  $t_{LOS}$  (see [图 21](#)). The current-sense amplifier is overdriven during this time and momentarily disables the internal current-limit MOSFET. The current-sense amplifier recovers and limits the output current to  $I_{OS}$ . Similar to the previous case, the TPS255x limits the current to  $I_{OS}$  until the overload condition is removed or the device begins to thermal cycle; the TPS255x-1 limits the current to  $I_{OS}$  until the overload condition is removed or the internal deglitch time is reached and the device is latched off.

The TPS255x thermal cycles if an overload condition is present long enough to activate thermal limiting in any of the above cases. The device turns off when the junction temperature exceeds 135°C (typical) while in current limit. The device remains off until the junction temperature cools 10°C (typical) and then restarts. The TPS255x cycles on and off until the overload is removed (see [图 5](#) and [图 7](#)).

### 9.3.2 Reverse-Voltage Protection

The reverse-voltage protection feature turns off the N-channel MOSFET whenever the output voltage exceeds the input voltage by 135 mV (typical) for 4-ms (typical). A reverse current of  $(V_{OUT} - V_{IN})/r_{DS(on)}$  are present when this occurs. This prevents damage to devices on the input side of the TPS255x and TPS2552-1/TPS2253-1 by preventing significant current from sinking into the input capacitance. The TPS255x devices allow the N-channel MOSFET to turn on once the output voltage goes below the input voltage for the same 4-ms deglitch time. The TPS255x-1 devices keep the device turned off even if the reverse-voltage condition is removed and do not allow the N-channel MOSFET to turn on until power is cycled or the device enable is toggled. The reverse-voltage comparator also asserts the **FAULT** output (active-low) after 4-ms.

### 9.3.3 **FAULT** Response

The **FAULT** open-drain output is asserted (active low) during an overcurrent, overtemperature, or reverse-voltage condition. The TPS255x asserts the **FAULT** signal until the fault condition is removed and the device resumes normal operation. The TPS255x-1 asserts the **FAULT** signal during a fault condition and remains asserted while the part is latched-off. The **FAULT** signal is de-asserted once device power is cycled or the enable is toggled and the device resumes normal operation. The TPS255x and TPS255x-1 are designed to eliminate false **FAULT** reporting by using an internal delay *de-glitch* circuit for overcurrent (7.5-ms typical) and reverse-voltage (4-ms typical) conditions without the need for external circuitry. This ensures that **FAULT** is not accidentally asserted due to normal operation such as starting into a heavy capacitive load. The deglitch circuitry delays entering and leaving fault conditions. Overtemperature conditions are not deglitched and assert the **FAULT** signal immediately.

### 9.3.4 Undervoltage Lockout (UVLO)

The undervoltage lockout (UVLO) circuit disables the power switch until the input voltage reaches the UVLO turnon threshold. Built-in hysteresis prevents unwanted on and off cycling due to input voltage drop from large current surges.

### 9.3.5 **ENABLE** ( $\overline{EN}$ or EN)

The logic enable controls the power switch, bias for the charge pump, driver, and other circuits to reduce the supply current. The supply current is reduced to less than 1- $\mu$ A when a logic low is present on EN. A logic low input on  $\overline{EN}$  or a logic high input on EN enables the driver, control circuits, and power switch. The enable input is compatible with both TTL and CMOS logic levels.

### 9.3.6 Thermal Sense

The TPS255x and TPS255x-1 have self-protection features using two independent thermal-sensing circuits that monitor the operating temperature of the power switch and disable operation if the temperature exceeds recommended operating conditions. The TPS255x device operates in constant-current mode during an overcurrent conditions, which increases the voltage drop across power-switch. The power dissipation in the package is proportional to the voltage drop across the power switch, which increases the junction temperature during an overcurrent condition. The first thermal sensor turns off the power switch when the die temperature exceeds 135°C (minimum) and the part is in current limit. Hysteresis is built into the thermal sensor, and the switch turns on after the device has cooled approximately 10°C.

## Feature Description (continued)

The TPS255x and TPS255x-1 also have a second ambient thermal sensor. The ambient thermal sensor turns off the power-switch when the die temperature exceeds 155°C (minimum) regardless of whether the power switch is in current limit and turns on the power switch after the device has cooled approximately 10°C. The TPS255x and TPS255x-1 families continue to cycle off and on until the fault is removed.

The open-drain fault reporting output **FAULT** is asserted (active low) immediately during an overtemperature shutdown condition.

## 9.4 Device Functional Modes

There are no other functional modes.

## 9.5 Programming

### 9.5.1 Programming the Current-Limit Threshold

The overcurrent threshold is user programmable through an external resistor. The TPS255x and TPS255x-1 use an internal regulation loop to provide a regulated voltage on the **ILIM** pin. The current-limit threshold is proportional to the current sourced out of **ILIM**. The recommended 1% resistor range for  $R_{ILIM}$  is  $15\text{ k}\Omega \leq R_{ILIM} \leq 232\text{ k}\Omega$  to ensure stability of the internal regulation loop. Many applications require that the minimum current limit is above a certain current level or that the maximum current limit is below a certain current level, so it is important to consider the tolerance of the overcurrent threshold when selecting a value for  $R_{ILIM}$ . The following equations and [Figure 23](#) can be used to calculate the resulting overcurrent threshold for a given external resistor value ( $R_{ILIM}$ ). [Figure 23](#) includes current-limit tolerance due to variations caused by temperature and process. However, the equations do not account for tolerance due to external resistor variation, so it is important to account for this tolerance when selecting  $R_{ILIM}$ . The traces routing the  $R_{ILIM}$  resistor to the TPS255x and TPS255x-1 must be as short as possible to reduce parasitic effects on the current-limit accuracy.

$R_{ILIM}$  can be selected to provide a current-limit threshold that occurs 1) above a minimum load current or 2) below a maximum load current.

To design above a minimum current-limit threshold, find the intersection of  $R_{ILIM}$  and the maximum desired load current on the  $I_{OS(max)}$  curve and choose a value of  $R_{ILIM}$  below this value. Programming the current limit above a minimum threshold is important to ensure start-up into full load or heavy capacitive loads. The resulting maximum current-limit threshold is the intersection of the selected value of  $R_{ILIM}$  and the  $I_{OS(max)}$  curve.

To design below a maximum current-limit threshold, find the intersection of  $R_{ILIM}$  and the maximum desired load current on the  $I_{OS(min)}$  curve and choose a value of  $R_{ILIM}$  above this value. Programming the current limit below a maximum threshold is important to avoid current limiting upstream power supplies, causing the input voltage bus to droop. The resulting minimum current-limit threshold is the intersection of the selected value of  $R_{ILIM}$  and the  $I_{OS(min)}$  curve.

Current-Limit Threshold Equations ( $I_{OS}$ ):

$$I_{OSmax}(\text{mA}) = \frac{22980\text{V}}{R_{ILIM}^{0.94\text{k}\Omega}}$$

$$I_{OSnom}(\text{mA}) = \frac{23950\text{V}}{R_{ILIM}^{0.977\text{k}\Omega}}$$

$$I_{OSmin}(\text{mA}) = \frac{25230\text{V}}{R_{ILIM}^{1.016\text{k}\Omega}}$$

where

$$15\text{ k}\Omega \leq R_{ILIM} \leq 232\text{ k}\Omega. \quad (1)$$

While the maximum recommended value of  $R_{ILIM}$  is 232 kΩ, there is one additional configuration that allows for a lower current-limit threshold. The **ILIM** pin may be connected directly to **IN** to provide a 75 mA (typical) current-limit threshold. Additional low-ESR ceramic capacitance may be necessary from **IN** to **GND** in this configuration to prevent unwanted noise from coupling into the sensitive **ILIM** circuitry.

## Programming (continued)

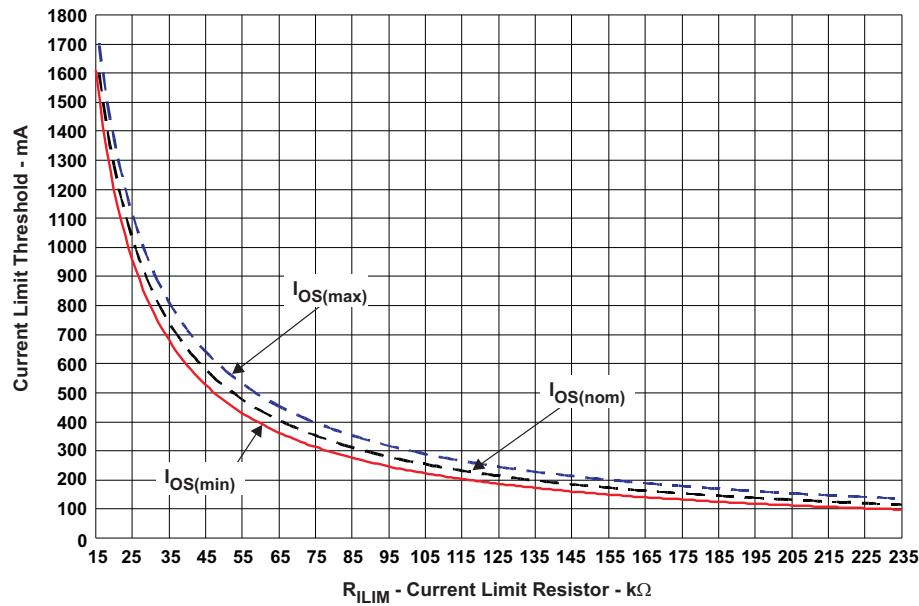


图 23. Current-Limit Threshold vs  $R_{ILIM}$

## 10 Application and Implementation

### 注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 10.1 Application Information

#### 10.1.1 Constant-Current vs Latch-Off Operation and Impact on Output Voltage

Both the constant-current devices (TPS255x) and latch-off devices (TPS255x-1) operate identically during normal operation, that is, the load current is less than the current-limit threshold and the devices are not limiting current. During normal operation the N-channel MOSFET is fully enhanced, and  $V_{OUT} = V_{IN} - (I_{OUT} \times r_{DS(on)})$ . The voltage drop across the MOSFET is relatively small compared to  $V_{IN}$ , and  $V_{OUT} \approx V_{IN}$ .

Both the constant-current devices (TPS255x) and latch-off devices (TPS255x-1) operate identically during the initial onset of an overcurrent event. Both devices limit current to the programmed current-limit threshold set to  $R_{ILIM}$  by operating the N-channel MOSFET in the linear mode. During current-limit operation, the N-channel MOSFET is no longer fully-enhanced and the resistance of the device increases. This allows the device to effectively regulate the current to the current-limit threshold. The effect of increasing the resistance of the MOSFET is that the voltage drop across the device is no longer negligible ( $V_{IN} \neq V_{OUT}$ ), and  $V_{OUT}$  decreases. The amount that  $V_{OUT}$  decreases is proportional to the magnitude of the overload condition. The expected  $V_{OUT}$  can be calculated by,

$$I_{OS} \times R_{LOAD}$$

where

$I_{OS}$  is the current-limit threshold and  $R_{LOAD}$  is the magnitude of the overload condition. (2)

For example, if  $I_{OS}$  is programmed to 1 A and a 1  $\Omega$  overload condition is applied, the resulting  $V_{OUT}$  is 1 V.

While both the constant-current devices (TPS255x) and latch-off devices (TPS255x-1) operate identically during the initial onset of an overcurrent event, they behave differently if the overcurrent event lasts longer than the internal delay *de-glitch* circuit (7.5-ms typical). The constant-current devices (TPS255x) assert the FAULT flag after the deglitch period and continue to regulate the current to the current-limit threshold indefinitely. In practical circuits, the power dissipation in the package increases the die temperature above the overtemperature shutdown threshold (135°C minimum), and the device turns off until the die temperature decreases by the hysteresis of the thermal shutdown circuit (10°C typical). The device turns on and continues to thermal cycle until the overload condition is removed. The constant-current devices resume normal operation once the overload condition is removed. The latch-off devices (TPS255x-1) assert the FAULT flag after the deglitch period and immediately turn off the device. The device remains off regardless of whether the overload condition is removed from the output. The latch-off devices remain off and do not resume normal operation until the surrounding system either toggles the enable or cycles power to the device.

### 10.2 Typical Applications

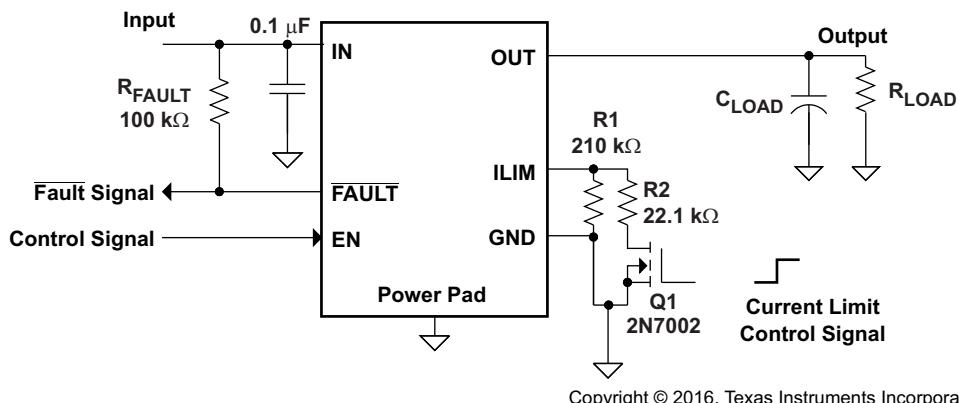
#### 10.2.1 Two-Level Current-Limit Circuit

Some applications require different current-limit thresholds depending on external system conditions. [图 24](#) shows an implementation for an externally controlled, two-level current-limit circuit. The current-limit threshold is set by the total resistance from ILIM to GND (see the [Programming the Current-Limit Threshold](#) section). A logic-level input enables or disables MOSFET Q1 and changes the current-limit threshold by modifying the total resistance from ILIM to GND. Additional MOSFET and resistor combinations can be used in parallel to Q1/R2 to increase the number of additional current-limit levels.

### 注

ILIM must never be driven directly with an external signal.

## Typical Applications (continued)



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图 24. Two-Level Current-Limit Circuit

### 10.2.1.1 Design Requirements

For this example, use the parameters shown in 表 1.

表 1. Design Requirements

| PARAMETER                     | VALUE   |
|-------------------------------|---------|
| Input voltage                 | 5 V     |
| Output voltage                | 5 V     |
| Above a minimum current limit | 1000 mA |
| Below a maximum current limit | 500 mA  |

### 10.2.1.2 Detailed Design Procedures

#### 10.2.1.2.1 Designing Above a Minimum Current Limit

Some applications require that current limiting cannot occur below a certain threshold. For this example, assume that 1 A must be delivered to the load so that the minimum desired current-limit threshold is 1000 mA. Use the  $I_{OS}$  equations and 图 23 to select  $R_{ILIM}$ :

$$\begin{aligned}
I_{OSmin}(\text{mA}) &= 1000 \text{mA} \\
I_{OSmin}(\text{mA}) &= \frac{25230V}{R_{ILIM}^{1.016}\text{k}\Omega} \\
R_{ILIM}(\text{k}\Omega) &= \left( \frac{25230V}{I_{OSmin}\text{mA}} \right)^{\frac{1}{1.016}} \\
R_{ILIM}(\text{k}\Omega) &= 24\text{k}\Omega
\end{aligned} \tag{3}$$

Select the closest 1% resistor less than the calculated value:  $R_{ILIM} = 23.7\text{k}\Omega$ . This sets the minimum current-limit threshold at 1 A. Use the  $I_{OS}$  equations, 图 23, and the previously calculated value for  $R_{ILIM}$  to calculate the maximum resulting current-limit threshold.

$$\begin{aligned}
R_{ILIM}(\text{k}\Omega) &= 23.7\text{k}\Omega \\
I_{OSmax}(\text{mA}) &= \frac{22980V}{R_{ILIM}^{0.94}\text{k}\Omega} \\
I_{OSmax}(\text{mA}) &= \frac{22980V}{23.7^{0.94}\text{k}\Omega} \\
I_{OSmax}(\text{mA}) &= 1172.4\text{mA}
\end{aligned} \tag{4}$$

The resulting maximum current-limit threshold is 1172.4 mA with a 23.7-kΩ resistor.

### 10.2.1.2.2 Designing Below a Maximum Current Limit

Some applications require that current limiting must occur below a certain threshold. For this example, assume that the desired upper current-limit threshold must be below 500 mA to protect an up-stream power supply. Use the  $I_{OS}$  equations and [图 23](#) to select  $R_{ILIM}$ .

$$I_{OSmax}(\text{mA}) = 500\text{mA}$$

$$I_{OSmax}(\text{mA}) = \frac{22980\text{V}}{R_{ILIM}^{0.94}\text{k}\Omega}$$

$$R_{ILIM}(\text{k}\Omega) = \left( \frac{22980\text{V}}{I_{OSmax}\text{mA}} \right)^{\frac{1}{0.94}}$$

$$R_{ILIM}(\text{k}\Omega) = 58.7\text{k}\Omega \quad (5)$$

Select the closest 1% resistor greater than the calculated value:  $R_{ILIM} = 59\text{-k}\Omega$ . This sets the maximum current-limit threshold at 500 mA. Use the  $I_{OS}$  equations, [图 23](#), and the previously calculated value for  $R_{ILIM}$  to calculate the minimum resulting current-limit threshold.

$$R_{ILIM}(\text{k}\Omega) = 59\text{k}\Omega$$

$$I_{OSmin}(\text{mA}) = \frac{25230\text{V}}{R_{ILIM}^{1.016}\text{k}\Omega}$$

$$I_{OSmin}(\text{mA}) = \frac{25230\text{V}}{59^{1.016}\text{k}\Omega}$$

$$I_{OSmin}(\text{mA}) = 400.6\text{mA} \quad (6)$$

The resulting minimum current-limit threshold is 400.6 mA with a 59-kΩ resistor.

### 10.2.1.2.3 Accounting for Resistor Tolerance

The previous sections described the selection of  $R_{ILIM}$  given certain application requirements and the importance of understanding the current-limit threshold tolerance. The analysis focused only on the TPS255x and TPS255x-1 performance and assumed an exact resistor value. However, resistors sold in quantity are not exact and are bounded by an upper and lower tolerance centered around a nominal resistance. The additional  $R_{ILIM}$  resistance tolerance directly affects the current-limit threshold accuracy at a system level. The following table shows a process that accounts for worst-case resistor tolerance assuming 1% resistor values. Step one follows the selection process outlined in the application examples above. Step two determines the upper and lower resistance bounds of the selected resistor. Step three uses the upper and lower resistor bounds in the  $I_{OS}$  equations to calculate the threshold limits. It is important to use tighter tolerance resistors, for example, 0.5% or 0.1%, when precision current limiting is desired.

表 2. Common  $R_{ILIM}$  Resistor Selections

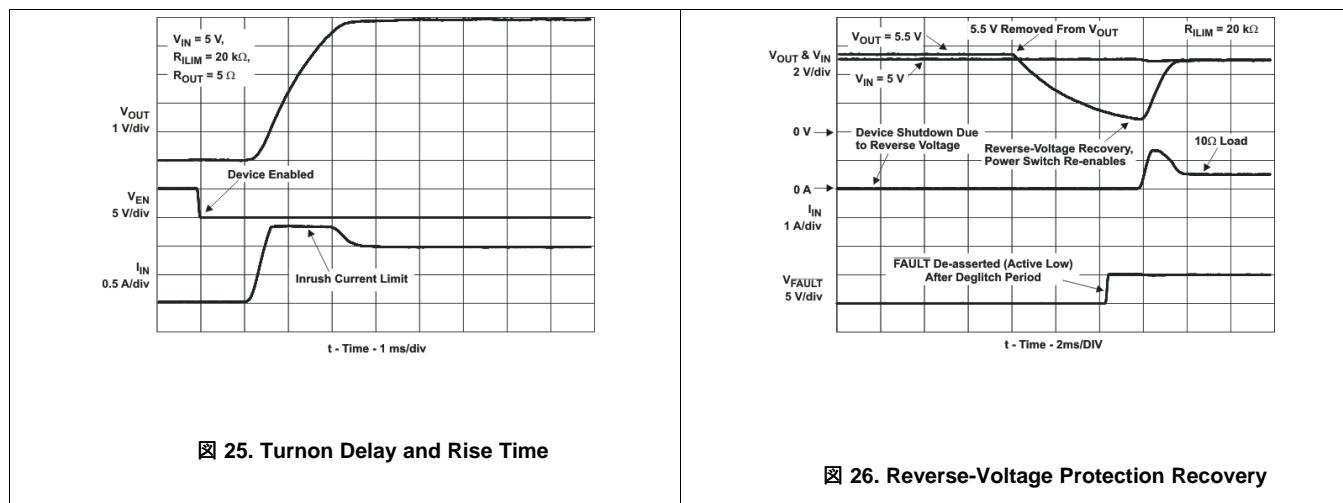
| DESIRED<br>NOMINAL<br>CURRENT<br>LIMIT<br>(mA) | IDEAL<br>RESISTOR<br>(k $\Omega$ ) | CLOSEST<br>1% RESISTOR<br>(k $\Omega$ ) | RESISTOR TOLERANCE   |                       | ACTUAL LIMITS |              |              |       |
|--|------------------------------------|---|----------------------|-----------------------|---------------|--------------|--------------|-------|
|  |                                    |   | 1% LOW (k $\Omega$ ) | 1% HIGH (k $\Omega$ ) | IOS MIN (mA)  | IOS NOM (mA) | IOS MAX (mA) |       |
| 75   |                                    |   | SHORT ILIM to IN     |                       |               | 50.0         | 75.0         | 100.0 |
| 120  | 226.1                              | 226                                     | 223.7                | 228.3                 | 101.3         | 120.0        | 142.1        |       |
| 200  | 134.0                              | 133                                     | 131.7                | 134.3                 | 173.7         | 201.5        | 233.9        |       |
| 300  | 88.5                               | 88.7                                    | 87.8                 | 89.6                  | 262.1         | 299.4        | 342.3        |       |
| 400  | 65.9                               | 66.5                                    | 65.8                 | 67.2                  | 351.2         | 396.7        | 448.7        |       |
| 500  | 52.5                               | 52.3                                    | 51.8                 | 52.8                  | 448.3         | 501.6        | 562.4        |       |
| 600  | 43.5                               | 43.2                                    | 42.8                 | 43.6                  | 544.3         | 604.6        | 673.1        |       |
| 700  | 37.2                               | 37.4                                    | 37.0                 | 37.8                  | 630.2         | 696.0        | 770.8        |       |
| 800  | 32.4                               | 32.4                                    | 32.1                 | 32.7                  | 729.1         | 800.8        | 882.1        |       |
| 900  | 28.7                               | 28.7                                    | 28.4                 | 29.0                  | 824.7         | 901.5        | 988.7        |       |
| 1000   | 25.8                               | 26.1                                    | 25.8                 | 26.4                  | 908.3         | 989.1        | 1081.0       |       |
| 1100   | 23.4                               | 23.2                                    | 23.0                 | 23.4                  | 1023.7        | 1109.7       | 1207.5       |       |
| 1200   | 21.4                               | 21.5                                    | 21.3                 | 21.7                  | 1106.0        | 1195.4       | 1297.1       |       |
| 1300   | 19.7                               | 19.6                                    | 19.4                 | 19.8                  | 1215.1        | 1308.5       | 1414.9       |       |
| 1400   | 18.3                               | 18.2                                    | 18.0                 | 18.4                  | 1310.1        | 1406.7       | 1517.0       |       |
| 1500   | 17.0                               | 16.9                                    | 16.7                 | 17.1                  | 1412.5        | 1512.4       | 1626.4       |       |
| 1600   | 16.0                               | 15.8                                    | 15.6                 | 16.0                  | 1512.5        | 1615.2       | 1732.7       |       |
| 1700   | 15.0                               | 15.0                                    | 14.9                 | 15.2                  | 1594.5        | 1699.3       | 1819.4       |       |

#### 10.2.1.2.4 Input and Output Capacitance

Input and output capacitance improves the performance of the device; the actual capacitance must be optimized for the particular application. For all applications, TI recommends placing a 0.1- $\mu$ F or greater ceramic bypass capacitor between IN and GND as close to the device as possible for local noise de-coupling. This precaution reduces ringing on the input due to power-supply transients. Additional input capacitance may be needed on the input to reduce voltage overshoot from exceeding the absolute maximum voltage of the device during heavy transient conditions. This is especially important during bench testing when long, inductive cables are used to connect the evaluation board to the bench power-supply.

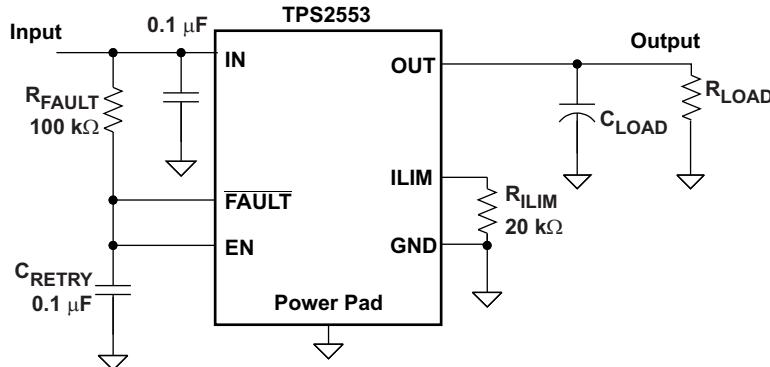
TI recommends placing a high-value electrolytic capacitor on the output pin when large transient currents are expected on the output.

#### 10.2.1.3 Application Curves



### 10.2.2 Auto-Retry Functionality

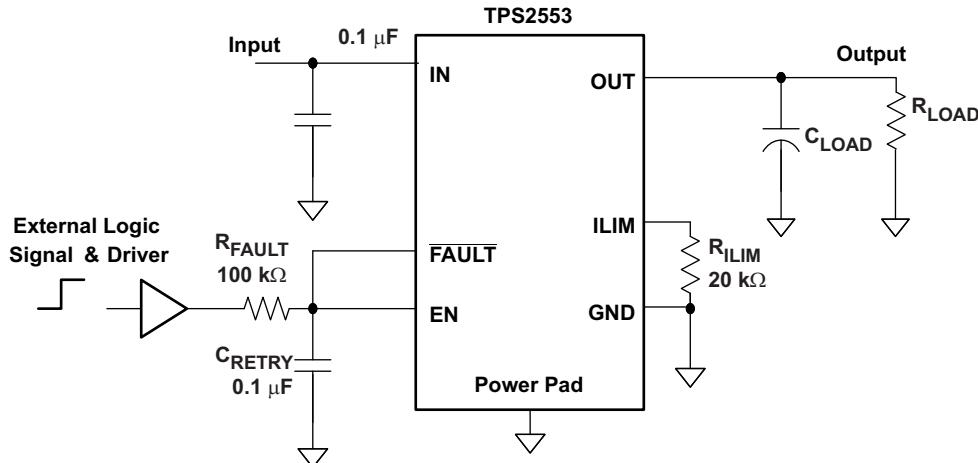
Some applications require that an overcurrent condition disables the part momentarily during a fault condition and re-enables after a pre-set time. This *auto-retry* functionality can be implemented with an external resistor and capacitor. During a fault condition,  $\overline{\text{FAULT}}$  pulls low disabling the part. The part is disabled when EN is pulled low, and  $\overline{\text{FAULT}}$  goes high impedance allowing  $C_{\text{RETRY}}$  to begin charging. The part re-enables when the voltage on EN reaches the turnon threshold, and the auto-retry time is determined by the resistor-capacitor time constant. The device continues to cycle in this manner until the fault condition is removed.



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**图 27. Auto-Retry Functionality**

Some applications require auto-retry functionality and the ability to enable or disable with an external logic signal. **图 28** shows how an external logic signal can drive EN through  $R_{\text{FAULT}}$  and maintain auto-retry functionality. The resistor-capacitor time constant determines the auto-retry time-out period.



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**图 28. Auto-Retry Functionality With External EN Signal**

#### 10.2.2.1 Design Requirements

For this example, use the parameters shown in **表 3**.

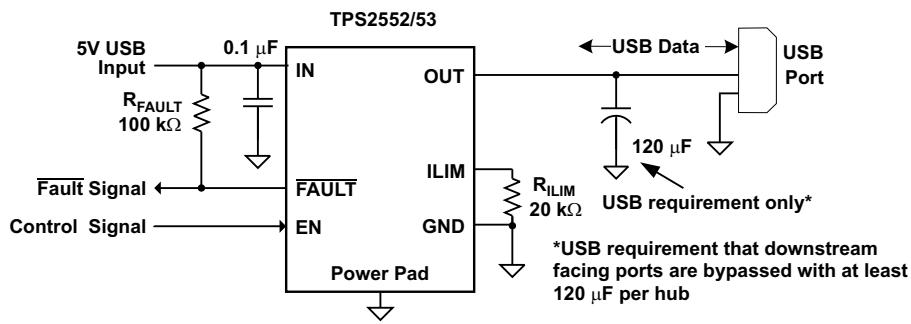
**表 3. Design Requirements**

| PARAMETER      | VALUE   |
|----------------|---------|
| Input voltage  | 5 V     |
| Output voltage | 5 V     |
| Current        | 1200 mA |

### 10.2.2.2 Detailed Design Procedure

Refer to [Programming the Current-Limit Threshold](#) section for the current limit setting. For auto-retry functionality, once  $\overline{\text{FAULT}}$  asserted, EN pull low, TPS2553 is disabled,  $\overline{\text{FAULT}}$  des-asserted,  $C_{\text{RETRY}}$  is slowly charged to EN logic high through  $R_{\text{FAULT}}$ , then enable, after deglitch time,  $\overline{\text{FAULT}}$  asserted again. In the event of an overload, TPS2553 cycles and has output average current. ON-time with output current is decided by  $\overline{\text{FAULT}}$  deglitch time. OFF-time without output current is decided by  $R_{\text{FAULT}} \times C_{\text{RETRY}}$  constant time to EN logic high and  $t_{\text{on}}$  time. Therefore, set the  $R_{\text{FAULT}} \times C_{\text{RETRY}}$  to get the desired output average current during overload.

### 10.2.3 Typical Application as USB Power Switch



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図 29. Typical Application as USB Power Switch

#### 10.2.3.1 Design Requirements

For this example, use the parameters shown in [表 4](#).

表 4. Design Requirements

| PARAMETER      | VALUE   |
|----------------|---------|
| Input voltage  | 5 V     |
| Output voltage | 5 V     |
| Current        | 1200 mA |

##### 10.2.3.1.1 USB Power-Distribution Requirements

USB can be implemented in several ways regardless of the type of USB device being developed. Several power-distribution features must be implemented.

- SPHs must:
  - Current limit downstream ports
  - Report overcurrent conditions
- BPHs must:
  - Enable or disable power to downstream ports
  - Power up at <100 mA
  - Limit inrush current (<44 Ω and 10  $\mu\text{F}$ )
- Functions must:
  - Limit inrush currents
  - Power up at <100 mA

The feature set of the TPS255x and TPS255x-1 meets each of these requirements. The integrated current limiting and overcurrent reporting is required by self-powered hubs. The logic-level enable and controlled rise times meet the need of both input and output ports on bus-powered hubs and the input ports for bus-powered functions.

### 10.2.3.2 Detailed Design Procedure

#### 10.2.3.2.1 Universal Serial Bus (USB) Power-Distribution Requirements

One application for this device is for current limiting in universal serial bus (USB) applications. The original USB interface was a 12-Mbps or 1.5-Mbps, multiplexed serial bus designed for low-to-medium bandwidth PC peripherals (for example, keyboards, printers, scanners, and mice). As the demand for more bandwidth increased, the USB 2.0 standard was introduced increasing the maximum data rate to 480-Mbps. The four-wire USB interface is conceived for dynamic attach-detach (hot plug-unplug) of peripherals. Two lines are provided for differential data, and two lines are provided for 5-V power distribution.

USB data is a 3.3-V level signal, but power is distributed at 5 V to allow for voltage drops in cases where power is distributed through more than one hub across long cables. Each function must provide its own regulated 3.3 V from the 5-V input or its own internal power supply. The USB specification classifies two different classes of devices depending on its maximum current draw. A device classified as low-power can draw up to 100 mA as defined by the standard. A device classified as high-power can draw up to 500 mA. It is important that the minimum current-limit threshold of the current-limiting power-switch exceed the maximum current-limit draw of the intended application. The latest USB standard must always be referenced when considering the current-limit threshold

The USB specification defines two types of devices as hubs and functions. A USB hub is a device that contains multiple ports for different USB devices to connect and can be self-powered (SPH) or bus-powered (BPH). A function is a USB device that is able to transmit or receive data or control information over the bus. A USB function can be embedded in a USB hub. A USB function can be one of three types included in the list below.

- Low-power, bus-powered function
- High-power, bus-powered function
- Self-powered function

SPHs and BPHs distribute data and power to downstream functions. The TPS255x has higher current capability than required for a single USB port allowing it to power multiple downstream ports.

## 11 Power Supply Recommendations

### 11.1 Self-Powered and Bus-Powered Hubs

A SPH has a local power supply that powers embedded functions and downstream ports. This power supply must provide between 4.75 V to 5.25 V to downstream facing devices under full-load and no-load conditions. SPHs are required to have current-limit protection and must report overcurrent conditions to the USB controller. Typical SPHs are desktop PCs, monitors, printers, and stand-alone hubs.

A BPH obtains all power from an upstream port and often contains an embedded function. It must power up with less than 100 mA. The BPH usually has one embedded function, and power is always available to the controller of the hub. If the embedded function and hub require more than 100 mA on power up, keep the power to the embedded function off until enumeration is completed. This can be accomplished by removing power or by shutting off the clock to the embedded function. Power-switching the embedded function is not necessary if the aggregate power draw for the function and controller is less than 100 mA. The total current drawn by the bus-powered device is the sum of the current to the controller, the embedded function, and the downstream ports, and it is limited to 500 mA from an upstream port.

### 11.2 Low-Power Bus-Powered and High-Power Bus-Powered Functions

Both low-power and high-power bus-powered functions obtain all power from upstream ports. Low-power functions always draw less than 100 mA; high-power functions must draw less than 100 mA at power up and can draw up to 500 mA after enumeration. If the load of the function is more than the parallel combination of  $44\ \Omega$  and  $10\ \mu F$  at power up, the device must implement inrush current limiting.

### 11.3 Power Dissipation and Junction Temperature

The low ON-resistance of the N-channel MOSFET allows small surface-mount packages to pass large currents. It is good design practice to estimate power dissipation and junction temperature. The below analysis gives an approximation for calculating junction temperature based on the power dissipation in the package. However, it is important to note that thermal analysis is strongly dependent on additional system level factors. Such factors include air flow, board layout, copper thickness and surface area, and proximity to other devices dissipating power. Good thermal design practice must include all system level factors in addition to individual component analysis.

Begin by determining the  $r_{DS(on)}$  of the N-channel MOSFET relative to the input voltage and operating temperature. As an initial estimate, use the highest operating ambient temperature of interest and read  $r_{DS(on)}$  from the typical characteristics graph. Using this value, the power dissipation can be calculated using [式 7](#).

$$P_D = r_{DS(on)} \times I_{OUT}^2$$

where

- $P_D$  = Total power dissipation (W)
- $r_{DS(on)}$  = Power switch on-resistance ( $\Omega$ )
- $I_{OUT}$  = Maximum current-limit threshold (A)
- This step calculates the total power dissipation of the N-channel MOSFET. (7)

Finally, calculate the junction temperature:

$$T_J = P_D \times \theta_{JA} + T_A$$

where

- $T_A$  = Ambient temperature ( $^{\circ}C$ )
- $\theta_{JA}$  = Thermal resistance ( $^{\circ}C/W$ )
- $P_D$  = Total power dissipation (W) (8)

Compare the calculated junction temperature with the initial estimate. If they are not within a few degrees, repeat the calculation using the refined  $r_{DS(on)}$  from the previous calculation as the new estimate. Two or three iterations are generally sufficient to achieve the desired result. The final junction temperature is highly dependent on thermal resistance  $\theta_{JA}$ , and thermal resistance is highly dependent on the individual package and board layout. The [Thermal Information](#) table provides example thermal resistances for specific packages and board layouts.

## 12 Layout

### 12.1 Layout Guidelines

- TI recommends placing the 100-nF bypass capacitor near the IN and GND pins, and make the connections using a low-inductance trace.
- TI recommends placing a high-value electrolytic capacitor and a 100-nF bypass capacitor on the output pin when large transient currents are expected on the output.
- The traces routing the RILIM resistor to the device must be as short as possible to reduce parasitic effects on the current limit accuracy.
- The PowerPAD must be directly connected to PCB ground plane using wide and short copper trace.

### 12.2 Layout Example

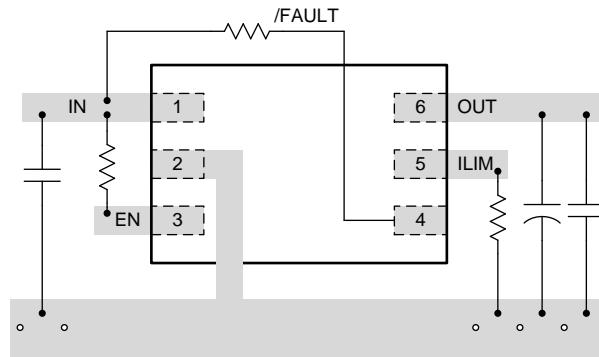


图 30. Layout Recommendation

## 13 デバイスおよびドキュメントのサポート

### 13.1 デバイス・サポート

TIスイッチのポートフォリオについては、[ここを参照](#)してください。

### 13.2 関連リンク

次の表に、クイック・アクセス・リンクを示します。カテゴリには、技術資料、サポートおよびコミュニティ・リソース、ツールとソフトウェア、およびサンプル注文またはご購入へのクイック・アクセスが含まれます。

**表 5. 関連リンク**

| 製品        | プロダクト・フォルダ              | サンプルとご購入                | 技術資料                    | ツールとソフトウェア              | サポートとコミュニティ             |
|-----------|-------------------------|-------------------------|-------------------------|-------------------------|-------------------------|
| TPS2552   | <a href="#">ここをクリック</a> |
| TPS2553   | <a href="#">ここをクリック</a> |
| TPS2552-1 | <a href="#">ここをクリック</a> |
| TPS2553-1 | <a href="#">ここをクリック</a> |

### 13.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](#)のデバイス製品フォルダを開いてください。右上の隅にある「通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

### 13.4 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** **TI's Engineer-to-Engineer (E2E) Community.** Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** **TI's Design Support** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 13.5 商標

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### 13.7 Glossary

**SLYZ022 — TI Glossary.**

This glossary lists and explains terms, acronyms, and definitions.

## 14 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。これらの情報は、指定のデバイスに対して提供されている最新のデータです。このデータは予告なく変更されることがあります。ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

**PACKAGING INFORMATION**

| Orderable part number         | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-------------------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPS2552DBVR</a>   | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2552                |
| <a href="#">TPS2552DBVR-1</a> | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHX                 |
| TPS2552DBVR-1.B               | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHX                 |
| TPS2552DBVR.B                 | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2552                |
| TPS2552DBVR1G4                | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2552                |
| TPS2552DBVR1G4.B              | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2552                |
| <a href="#">TPS2552DBVT</a>   | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2552                |
| <a href="#">TPS2552DBVT-1</a> | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHX                 |
| TPS2552DBVT-1.B               | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHX                 |
| TPS2552DBVT-11G4              | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHX                 |
| TPS2552DBVT-11G4.B            | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHX                 |
| TPS2552DBVT.B                 | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2552                |
| <a href="#">TPS2552DRV</a>    | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHR                 |
| <a href="#">TPS2552DRV-1</a>  | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHY                 |
| TPS2552DRV-1.B                | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHY                 |
| TPS2552DRV.R                  | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHR                 |
| TPS2552DRV.RG4                | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHR                 |
| TPS2552DRV.RG4.B              | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHR                 |
| <a href="#">TPS2552DRV</a>    | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CHR                 |
| <a href="#">TPS2552DRV-1</a>  | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHY                 |
| TPS2552DRV-1.B                | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHY                 |
| TPS2552DRV-1G4                | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHY                 |
| TPS2552DRV-1G4.B              | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHY                 |
| TPS2552DRV.T                  | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 85    | CHR                 |
| <a href="#">TPS2553DBVR</a>   | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2553                |
| <a href="#">TPS2553DBVR-1</a> | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU   SN                          | Level-1-260C-UNLIM                | -40 to 125   | CHZ                 |
| TPS2553DBVR-1.B               | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHZ                 |
| TPS2553DBVR-11G4              | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHZ                 |
| TPS2553DBVR-11G4.B            | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHZ                 |

| Orderable part number | Status<br>(1) | Material type<br>(2) | Package   Pins   | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-----------------------|---------------|----------------------|------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| TPS2553DBVR.A         | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2553                |
| TPS2553DBVR.B         | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2553                |
| TPS2553DBVRG4         | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2553                |
| TPS2553DBVRG4.A       | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2553                |
| TPS2553DBVRG4.B       | Active        | Production           | SOT-23 (DBV)   6 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2553                |
| <b>TPS2553DBVT</b>    | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2553                |
| <b>TPS2553DBVT-1</b>  | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHZ                 |
| TPS2553DBVT-1.B       | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHZ                 |
| TPS2553DBVT.A         | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2553                |
| TPS2553DBVT.B         | Active        | Production           | SOT-23 (DBV)   6 | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | 2553                |
| <b>TPS2553DRV</b>     | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHT                 |
| <b>TPS2553DRV-1</b>   | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CJZ                 |
| TPS2553DRV-1.B        | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CJZ                 |
| TPS2553DRV.R          | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHT                 |
| TPS2553DRV.R.B        | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHT                 |
| TPS2553DRV.RG4        | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHT                 |
| TPS2553DRV.RG4.A      | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHT                 |
| TPS2553DRV.RG4.B      | Active        | Production           | WSON (DRV)   6   | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHT                 |
| <b>TPS2553DRV</b>     | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHT                 |
| <b>TPS2553DRV-1</b>   | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CJZ                 |
| TPS2553DRV-1.B        | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CJZ                 |
| TPS2553DRV-1G4        | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CJZ                 |
| TPS2553DRV-1G4.B      | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CJZ                 |
| TPS2553DRV.T          | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHT                 |
| TPS2553DRV.T.B        | Active        | Production           | WSON (DRV)   6   | 250   SMALL T&R       | Yes         | NIPDAU                               | Level-1-260C-UNLIM                | -40 to 125   | CHT                 |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

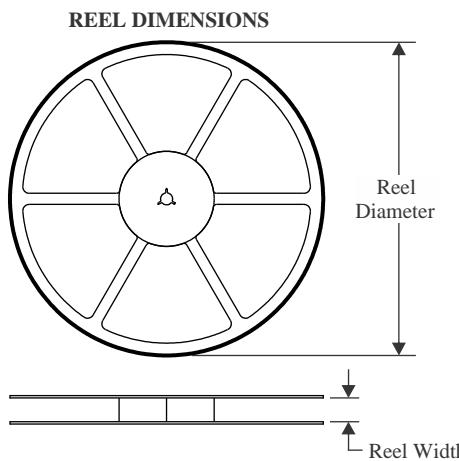
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TPS2553, TPS2553-1 :**

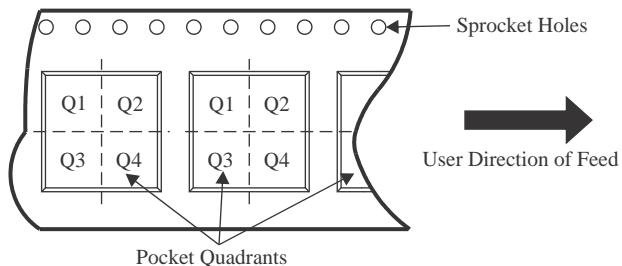
- Automotive : [TPS2553-Q1](#), [TPS2553-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

**TAPE AND REEL INFORMATION**


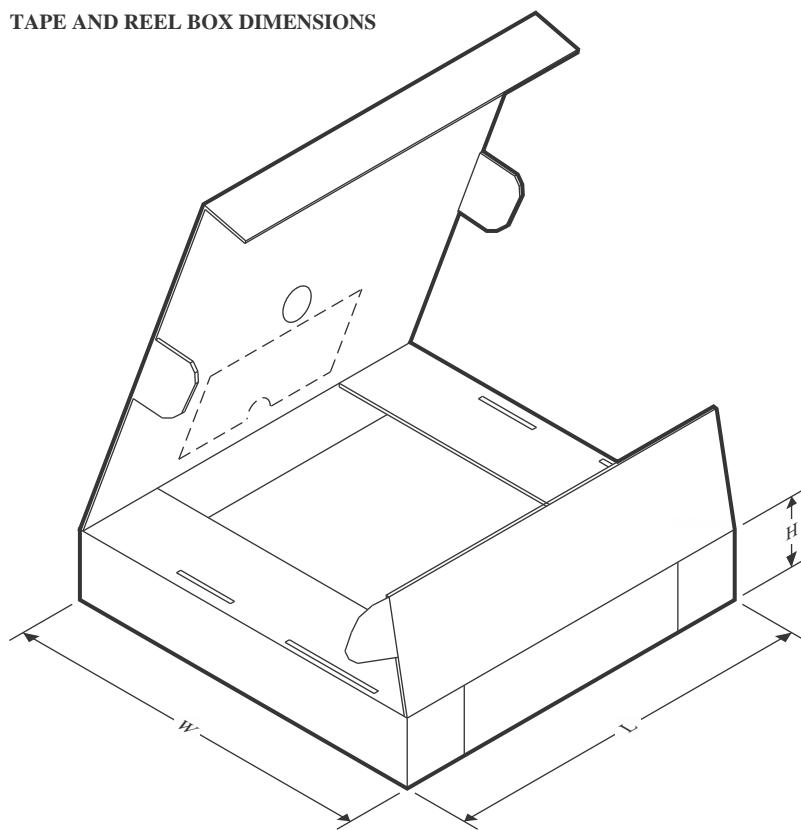
|    |   |
|----|---|
| A0 | Dimension designed to accommodate the component width     |
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS2552DBVR      | SOT-23       | DBV             | 6    | 3000 | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2552DBVR-1    | SOT-23       | DBV             | 6    | 3000 | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| TPS2552DBVR1G4   | SOT-23       | DBV             | 6    | 3000 | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2552DBVT      | SOT-23       | DBV             | 6    | 250  | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2552DBVT-1    | SOT-23       | DBV             | 6    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| TPS2552DBVT-1    | SOT-23       | DBV             | 6    | 250  | 179.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2552DBVT-11G4 | SOT-23       | DBV             | 6    | 250  | 178.0              | 9.0                | 3.23    | 3.17    | 1.37    | 4.0     | 8.0    | Q3            |
| TPS2552DRVR      | WSON         | DRV             | 6    | 3000 | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2552DRVR      | WSON         | DRV             | 6    | 3000 | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2552DRVR-1    | WSON         | DRV             | 6    | 3000 | 179.0              | 8.4                | 2.2     | 2.2     | 1.2     | 4.0     | 8.0    | Q2            |
| TPS2552DRVRC4    | WSON         | DRV             | 6    | 3000 | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2552DRVTR     | WSON         | DRV             | 6    | 250  | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2552DRVTR-1   | WSON         | DRV             | 6    | 250  | 179.0              | 8.4                | 2.2     | 2.2     | 1.2     | 4.0     | 8.0    | Q2            |
| TPS2552DRVTR-1G4 | WSON         | DRV             | 6    | 250  | 179.0              | 8.4                | 2.2     | 2.2     | 1.2     | 4.0     | 8.0    | Q2            |
| TPS2553DBVR      | SOT-23       | DBV             | 6    | 3000 | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2553DBVR-1    | SOT-23       | DBV             | 6    | 3000 | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |

| Device           | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS2553DBVR-11G4 | SOT-23       | DBV             | 6    | 3000 | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2553DBVRG4    | SOT-23       | DBV             | 6    | 3000 | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2553DBVT      | SOT-23       | DBV             | 6    | 250  | 179.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2553DBVT      | SOT-23       | DBV             | 6    | 250  | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2553DBVT-1    | SOT-23       | DBV             | 6    | 250  | 180.0              | 8.4                | 3.2     | 3.2     | 1.4     | 4.0     | 8.0    | Q3            |
| TPS2553DRV       | WSON         | DRV             | 6    | 3000 | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2553DRV-1     | WSON         | DRV             | 6    | 3000 | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2553DRV-1     | WSON         | DRV             | 6    | 3000 | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2553DRV       | WSON         | DRV             | 6    | 3000 | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2553DRV       | WSON         | DRV             | 6    | 250  | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2553DRV-1     | WSON         | DRV             | 6    | 250  | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |
| TPS2553DRV-1G4   | WSON         | DRV             | 6    | 250  | 180.0              | 8.4                | 2.3     | 2.3     | 1.15    | 4.0     | 8.0    | Q2            |

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS2552DBVR      | SOT-23       | DBV             | 6    | 3000 | 210.0       | 185.0      | 35.0        |
| TPS2552DBVR-1    | SOT-23       | DBV             | 6    | 3000 | 180.0       | 180.0      | 18.0        |
| TPS2552DBVR1G4   | SOT-23       | DBV             | 6    | 3000 | 210.0       | 185.0      | 35.0        |
| TPS2552DBVT      | SOT-23       | DBV             | 6    | 250  | 210.0       | 185.0      | 35.0        |
| TPS2552DBVT-1    | SOT-23       | DBV             | 6    | 250  | 180.0       | 180.0      | 18.0        |
| TPS2552DBVT-1    | SOT-23       | DBV             | 6    | 250  | 203.0       | 203.0      | 35.0        |
| TPS2552DBVT-11G4 | SOT-23       | DBV             | 6    | 250  | 180.0       | 180.0      | 18.0        |
| TPS2552DRVR      | WSON         | DRV             | 6    | 3000 | 210.0       | 185.0      | 35.0        |
| TPS2552DRVR      | WSON         | DRV             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| TPS2552DRVR-1    | WSON         | DRV             | 6    | 3000 | 200.0       | 183.0      | 25.0        |
| TPS2552DRVRG4    | WSON         | DRV             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| TPS2552DRV       | WSON         | DRV             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| TPS2552DRV-1     | WSON         | DRV             | 6    | 250  | 200.0       | 183.0      | 25.0        |
| TPS2552DRV-1G4   | WSON         | DRV             | 6    | 250  | 200.0       | 183.0      | 25.0        |
| TPS2553DBVR      | SOT-23       | DBV             | 6    | 3000 | 210.0       | 185.0      | 35.0        |
| TPS2553DBVR-1    | SOT-23       | DBV             | 6    | 3000 | 210.0       | 185.0      | 35.0        |
| TPS2553DBVR-11G4 | SOT-23       | DBV             | 6    | 3000 | 210.0       | 185.0      | 35.0        |
| TPS2553DBVRG4    | SOT-23       | DBV             | 6    | 3000 | 210.0       | 185.0      | 35.0        |

| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS2553DBVT      | SOT-23       | DBV             | 6    | 250  | 200.0       | 183.0      | 25.0        |
| TPS2553DBVT      | SOT-23       | DBV             | 6    | 250  | 210.0       | 185.0      | 35.0        |
| TPS2553DBVT-1    | SOT-23       | DBV             | 6    | 250  | 210.0       | 185.0      | 35.0        |
| TPS2553DRVVR     | WSON         | DRV             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| TPS2553DRVVR-1   | WSON         | DRV             | 6    | 3000 | 210.0       | 185.0      | 35.0        |
| TPS2553DRVVR-1   | WSON         | DRV             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| TPS2553DRVVRG4   | WSON         | DRV             | 6    | 3000 | 182.0       | 182.0      | 20.0        |
| TPS2553DRVVT     | WSON         | DRV             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| TPS2553DRVVT-1   | WSON         | DRV             | 6    | 250  | 182.0       | 182.0      | 20.0        |
| TPS2553DRVVT-1G4 | WSON         | DRV             | 6    | 250  | 182.0       | 182.0      | 20.0        |

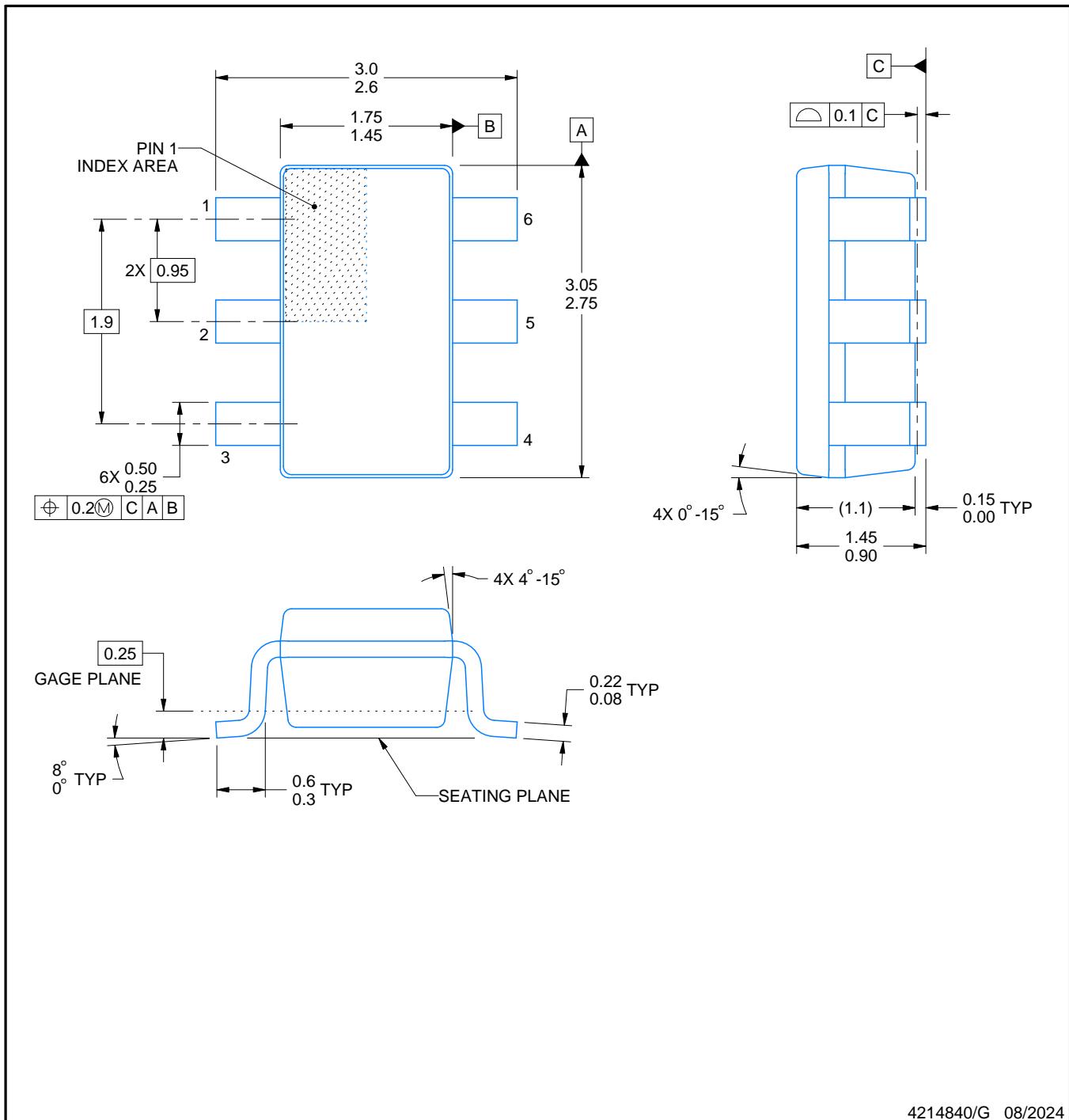
## PACKAGE OUTLINE

**DBV0006A**



## **SOT-23 - 1.45 mm max height**

## SMALL OUTLINE TRANSISTOR



4214840/G 08/2024

## NOTES:

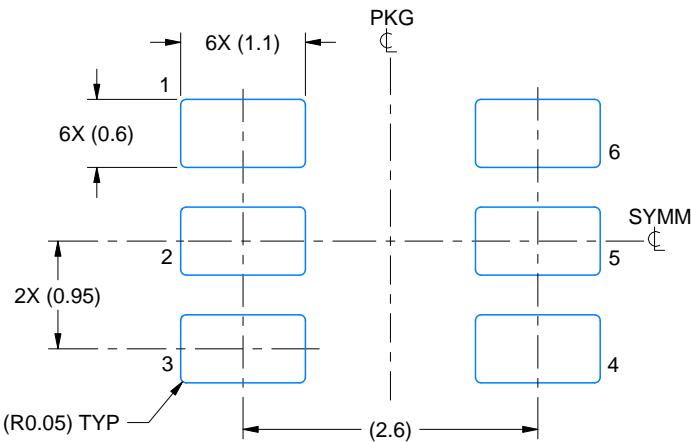
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Reference JEDEC MO-178.

# EXAMPLE BOARD LAYOUT

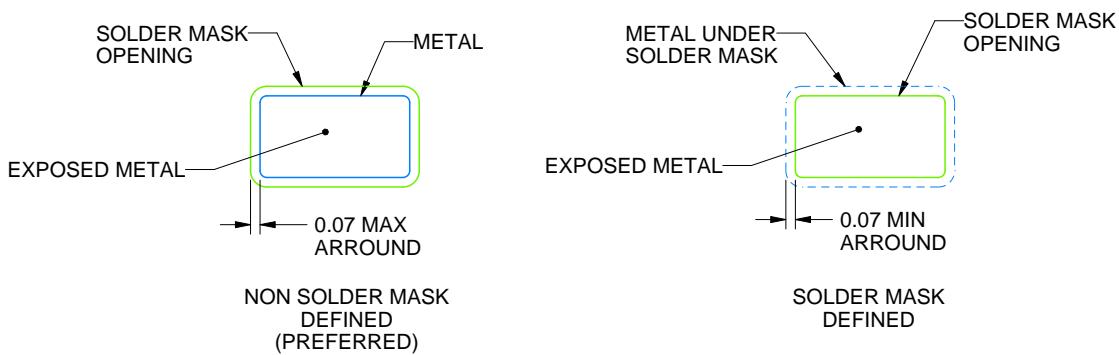
DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

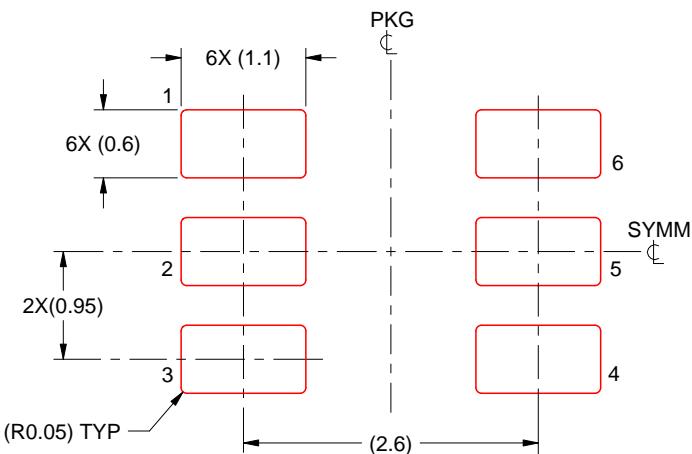
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

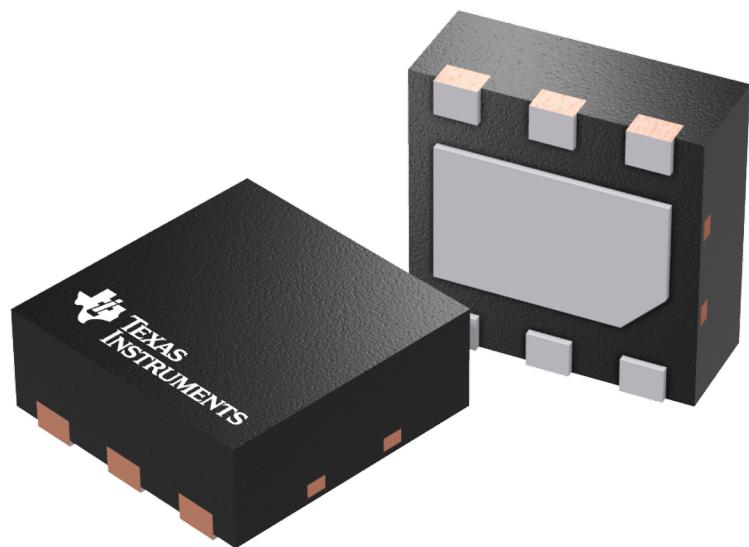
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

**DRV 6**

**GENERIC PACKAGE VIEW**

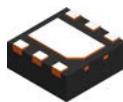
**WSON - 0.8 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4206925/F

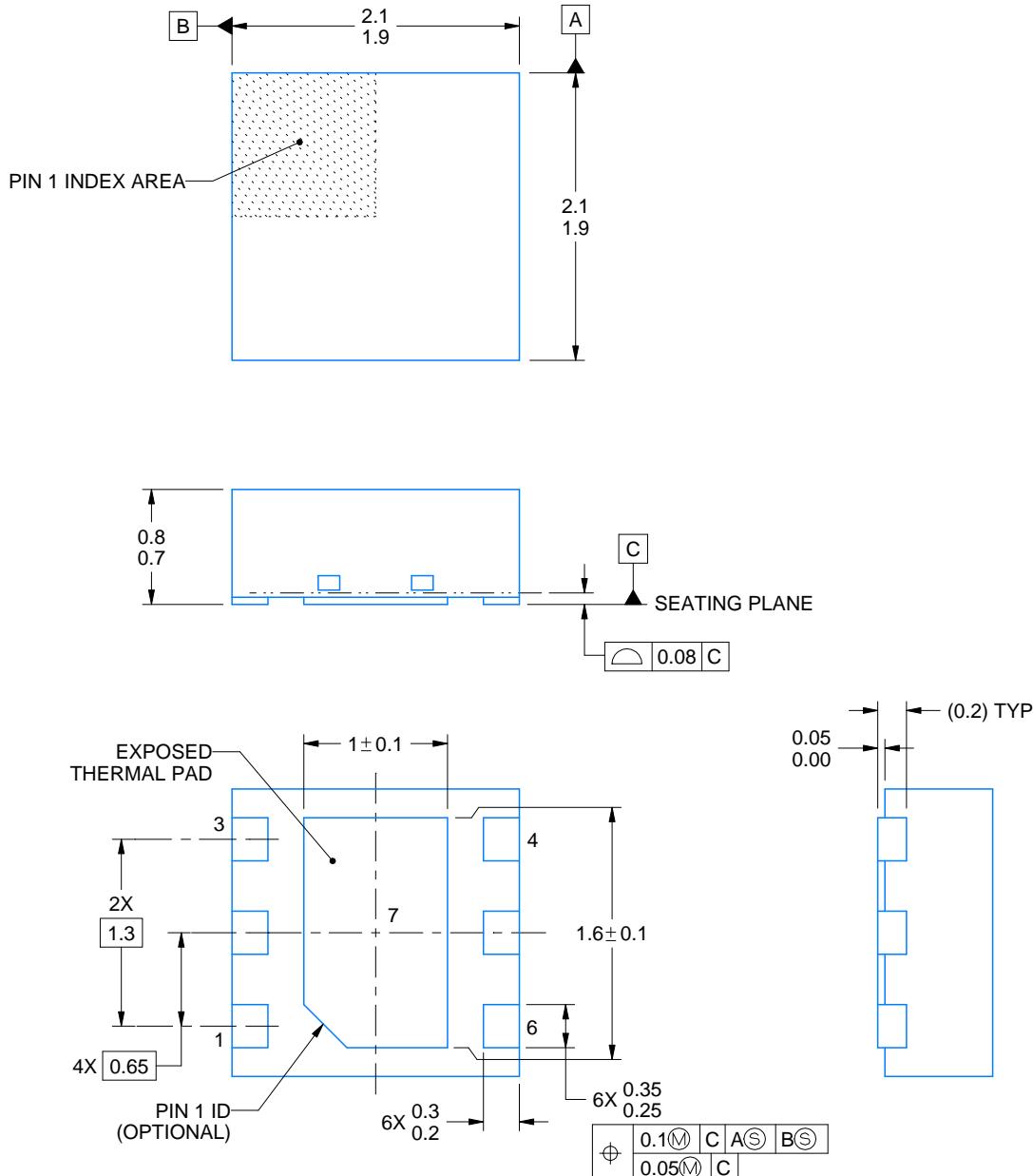


# PACKAGE OUTLINE

**DRV0006A**

**WSON - 0.8 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



4222173/B 04/2018

## NOTES:

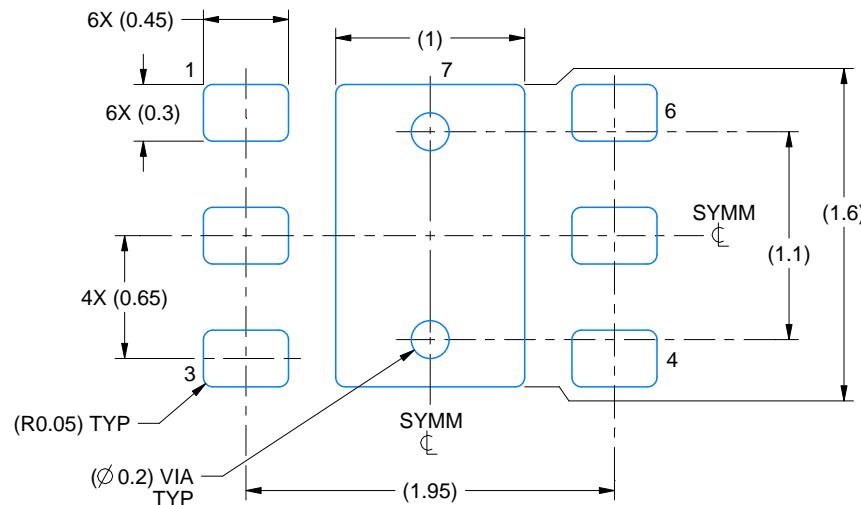
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

DRV0006A

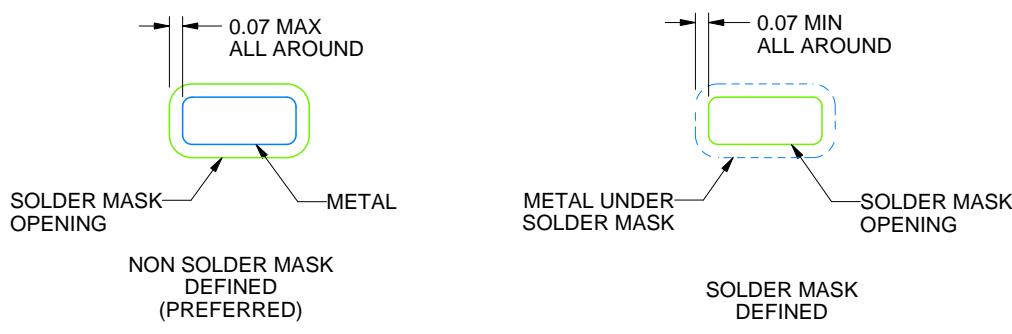
WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE

SCALE:25X



SOLDER MASK DETAILS

4222173/B 04/2018

NOTES: (continued)

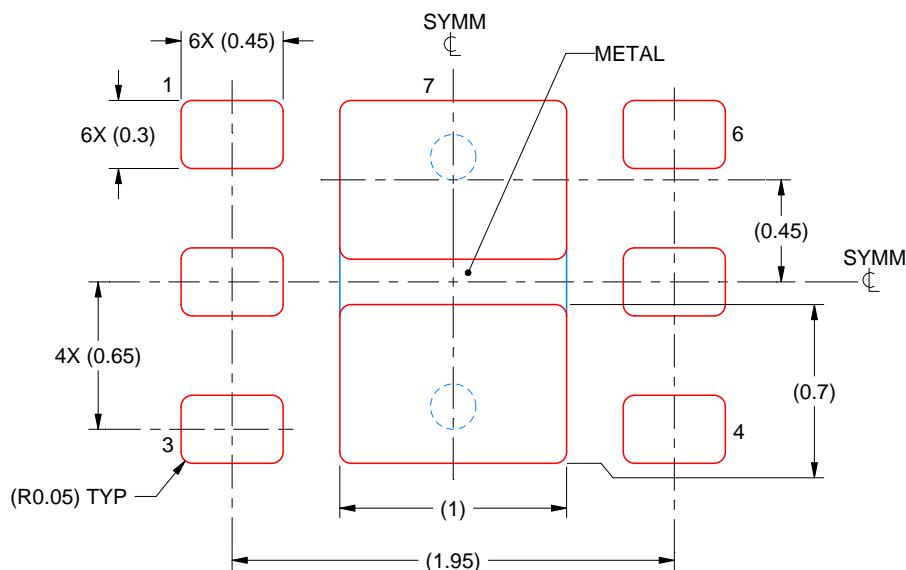
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

# EXAMPLE STENCIL DESIGN

DRV0006A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7  
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:30X

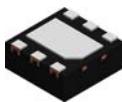
4222173/B 04/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

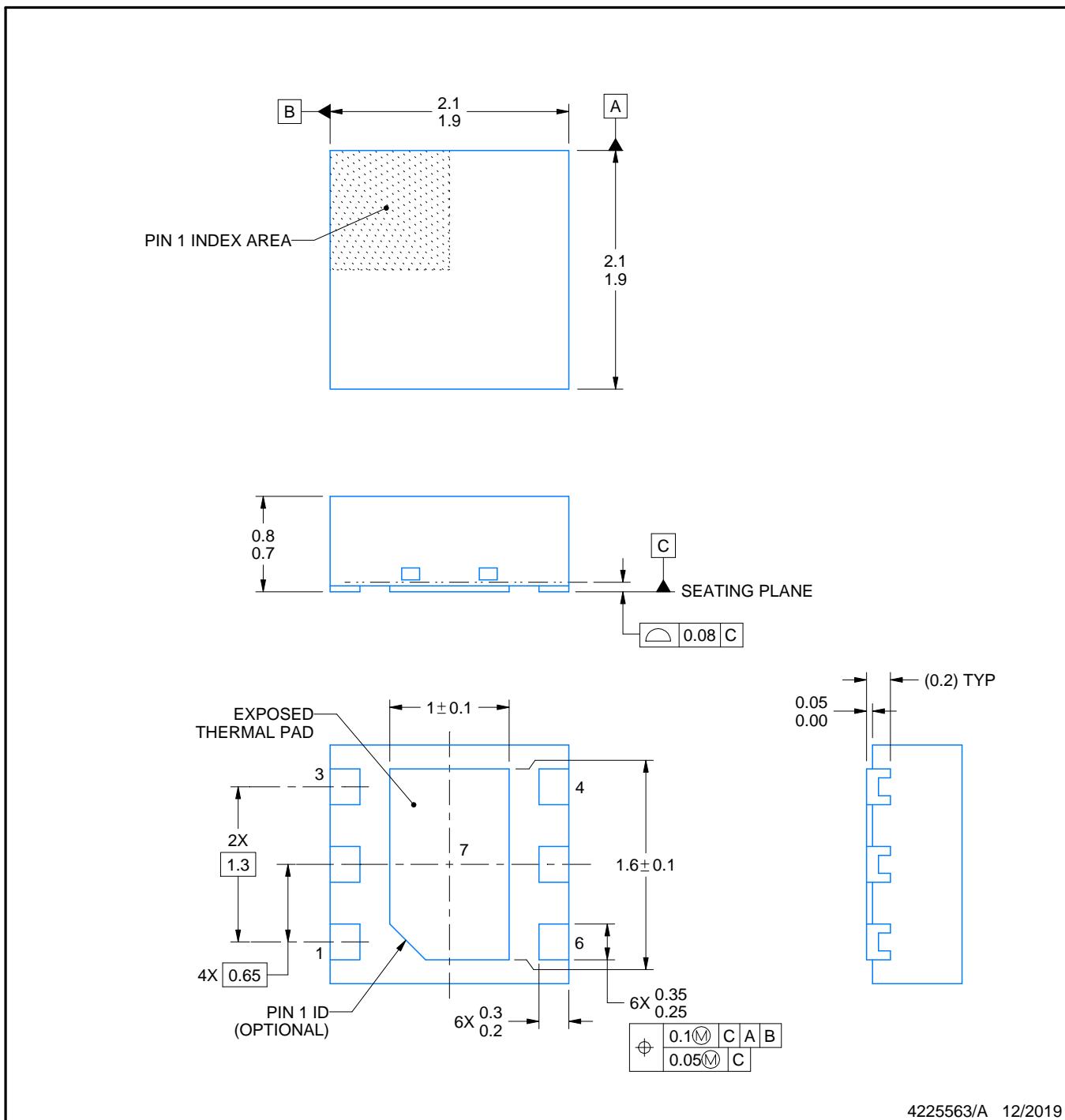
# PACKAGE OUTLINE

DRV0006D



WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4225563/A 12/2019

## NOTES:

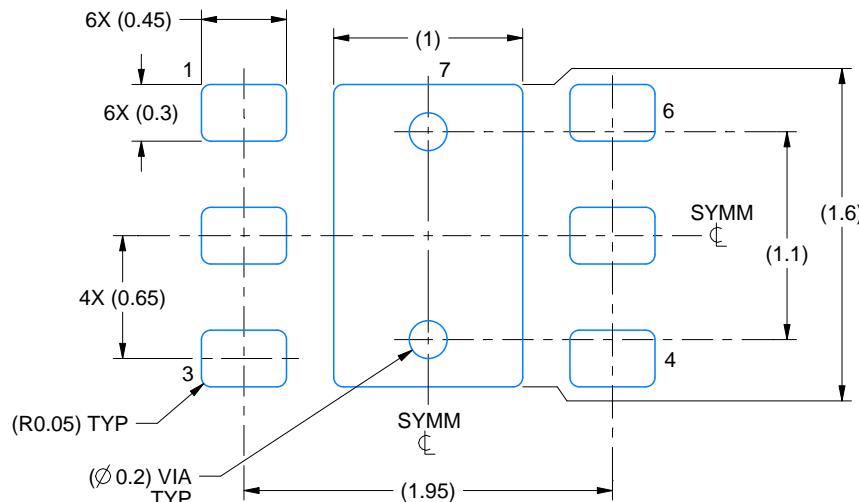
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

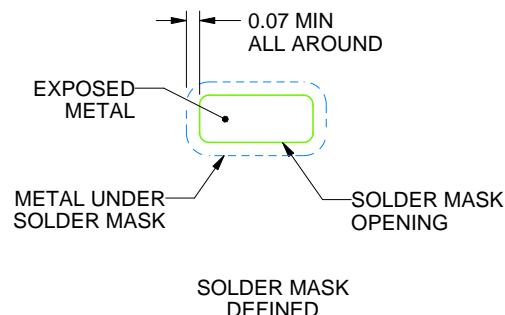
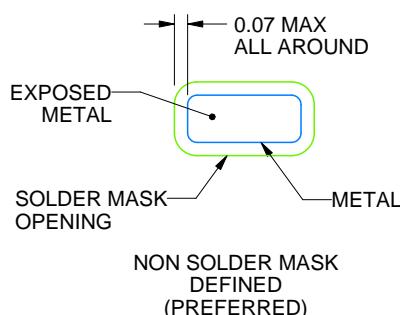
DRV0006D

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:25X



SOLDER MASK DETAILS

4225563/A 12/2019

NOTES: (continued)

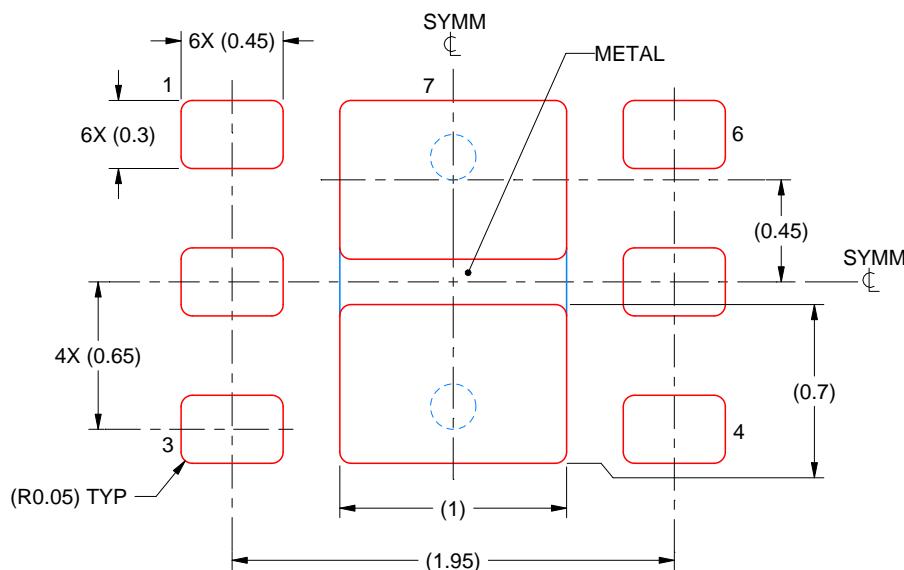
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

# EXAMPLE STENCIL DESIGN

DRV0006D

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7  
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:30X

4225563/A 12/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

## 重要なお知らせと免責事項

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